FAMILY OF 600µA/Ch 2.8MHz RAIL-TO-RAIL INPUT/OUTPUT HIGH-DRIVE OPERATIONAL AMPLIFIERS WITH SHUTDOWN

FEATURES

- **CMOS Rail-To-Rail Input/Output**
- **Input Bias Current: 2.5pA**
- **Low Supply Current: 600µA/Channel**
- **Ultra-Low Power Shutdown Mode:**
  $I_{DD(SHDN)}$: 350nA/ch at 3V
  $I_{DD(SHDN)}$: 1000nA/ch at 5V
- **Gain-Bandwidth Product: 2.8MHz**
- **High Output Drive Capability:**
  - **±10mA at 180mV**
  - **±35mA at 500mV**
- **Input Offset Voltage: 250µV (typ)**
- **Supply Voltage Range: 2.7V to 6V**
- **Ultra-Small Packaging**
  - **SOT23-5 or -6 (TLV2470/1)**
  - **MSOP-8 or -10 (TLV2472/3)**

DESCRIPTION

The TLV247x is a family of CMOS rail-to-rail input/output operational amplifiers that establishes a new performance point for supply current versus ac performance. These devices consume just 600µA/channel while offering 2.8MHz of gain-bandwidth product. Along with increased ac performance, the amplifier provides high output drive capability, solving a major shortcoming of older micropower operational amplifiers. The TLV247x can swing to within 180mV of each supply rail while driving a 10mA load. For non-RRO applications, the TLV247x can supply ±35mA at 500mV off the rail. Both the inputs and outputs swing rail-to-rail for increased dynamic range in low-voltage applications. This performance makes the TLV247x family ideal for sensor interface, portable medical equipment, and other data acquisition circuits.

FAMILY PACKAGE TABLE

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES					SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	SOIC	SOT23	TSSOP	MSOP		
TLV2470	1	8	8	6	—	—	Yes	Refer to the EVM Selection Guide (SLOU060)
TLV2471	1	8	8	5	—	—	—	
TLV2472	2	8	8	—	—	8	—	
TLV2473	2	14	14	—	—	10	Yes	
TLV2474	4	14	14	—	14	—	—	
TLV2475	4	16	16	—	16	—	Yes	

A SELECTION OF SINGLE-SUPPLY OPERATIONAL AMPLIFIER PRODUCTS(1)

DEVICE	V_{DD} (V)	V_{IO} (µV)	BW (MHz)	SLEW RATE (V/µs)	I_{DD} (per channel) (µA)	OUTPUT DRIVE	RAIL-TO-RAIL
TLV247X	2.7 – 6.0	250	2.8	1.5	600	±35mA	I/O
TLV245X	2.7 – 6.0	20	0.22	0.11	23	±10mA	I/O
TLV246X	2.7 – 6.0	150	6.4	1.6	550	±90mA	I/O
TLV277X	2.5 – 6.0	360	5.1	10.5	1000	±10mA	O

(1) All specifications measured at 5V.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

TLV2470 and TLV2471 AVAILABLE OPTIONS(1)

T_A	PACKAGED DEVICES			
	SMALL OUTLINE (D)(2)	SOT23		PLASTIC DIP (P)
		(DBV)(2)	SYMBOL	
0°C to +70°C	TLV2470CD TLV2471CD	TLV2470CDBV TLV2471CDBV	VAUC VAVC	TLV2470CP TLV2471CP
–40°C to +125°C	TLV2470ID TLV2471ID	TLV2470IDBV TLV2471IDBV	VAUI VAVI	TLV2470IP TLV2471IP
	TLV2470AID TLV2471AID	—	—	TLV2470AIP TLV2471AIP

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (for example, TLV2470CDR).

TLV2472 AND TLV2473 AVAILABLE OPTIONS(1)

T_A	PACKAGED DEVICES						
	SMALL OUTLINE (D)(2)	MSOP		MSOP		PLASTIC DIP (N)	PLASTIC DIP (P)
		(DGN)(2)	SYMBOL(3)	(DGQ)(2)	SYMBOL(3)		
0°C to +70°C	TLV2472CD TLV2473CD	TLV2472CDGN —	xxTIABU —	— TLV2473CDGQ	— xxTIABW	— TLV2473CN	TLV2472CP —
–40°C to +125°C	TLV2472ID TLV2473ID	TLV2472IDGN —	xxTIABV —	— TLV2473IDGQ	— xxTIABX	— TLV2473IN	TLV2472IP —
	TLV2472AID TLV2473AID	—	—	—	—	— TLV2473AIN	TLV2472AIP —

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (for example, TLV2472CDR).
(3) xx represents the device date code.

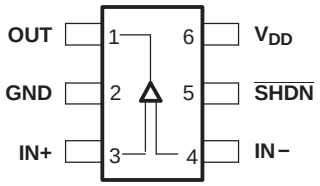
TLV2474 and TLV2475 AVAILABLE OPTIONS(1)

T_A	PACKAGED DEVICES		
	SMALL OUTLINE (D)(2)	PLASTIC DIP (N)	TSSOP (PWP)(2)
0°C to +70°C	TLV2474CD TLV2475CD	TLV2474CN TLV2475CN	TLV2474CPWP TLV2475CPWP
–40°C to +125°C	TLV2474ID TLV2475ID	TLV2474IN TLV2475IN	TLV2474IPWP TLV2475IPWP
	TLV2474AID TLV2475AID	TLV2474AIN TLV2475AIN	TLV2474AIPWP TLV2475AIPWP

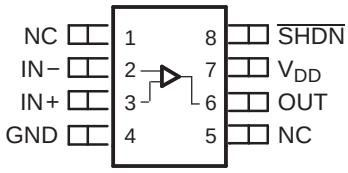
(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (for example, TLV2474CDR).

TLV247X PACKAGE PINOUTS

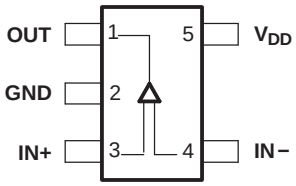
TLV2470
DBV PACKAGE
(TOP VIEW)



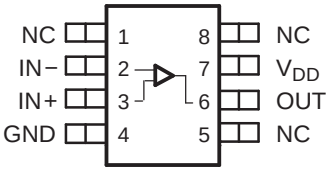
TLV2470
D OR P PACKAGE
(TOP VIEW)



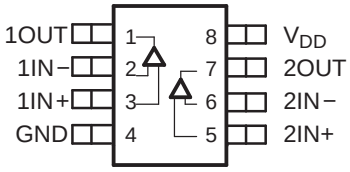
TLV2471
DBV PACKAGE
(TOP VIEW)



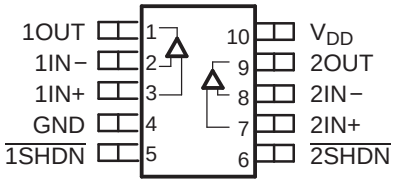
TLV2471
D OR P PACKAGE
(TOP VIEW)



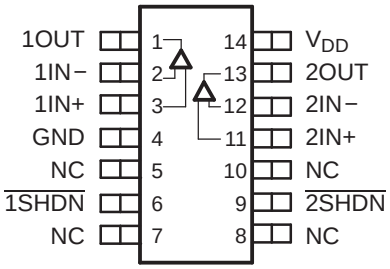
TLV2472
D, DGN, OR P PACKAGE
(TOP VIEW)



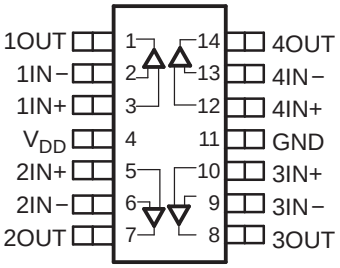
TLV2473
DGQ PACKAGE
(TOP VIEW)



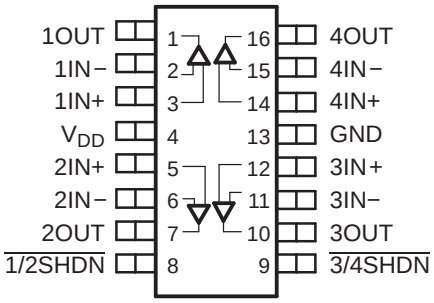
TLV2473
D OR N PACKAGE
(TOP VIEW)



TLV2474
D, N, OR PWP PACKAGE
(TOP VIEW)

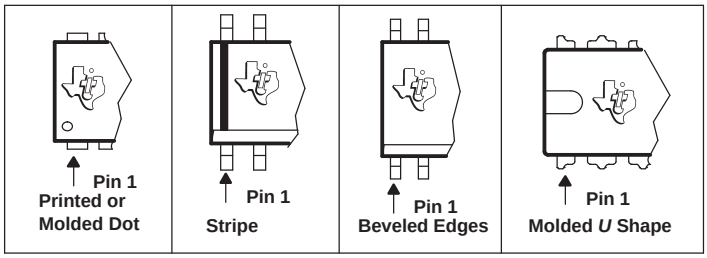


TLV2475
D, N, OR PWP PACKAGE
(TOP VIEW)



NC − No internal connection

TYPICAL PIN 1 INDICATORS



DESCRIPTION (CONTINUED)

Three members of the family (TLV2470/3/5) offer a shutdown terminal for conserving battery life in portable applications. During shutdown, the outputs are placed in a high-impedance state and the amplifier consumes only 350nA/channel. The family is fully specified at 3V and 5V across an expanded industrial temperature range (–40°C to +125°C). The singles and duals are available in the SOT23 and MSOP packages, while the quads are available in TSSOP. The TLV2470 offers an amplifier with shutdown functionality all in a SOT23-6 package, making it perfect for high-density power-sensitive circuits.

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range, unless otherwise noted.

		UNIT
Supply voltage, V_{DD}(2)		7V
Differential input voltage, V_{ID}		$\pm V_{DD}$
Continuous total power dissipation		See Dissipation Rating table
Operating free-air temperature range, T_A	C-suffix	0°C to +70°C
	I-suffix	–40°C to +125°C
Maximum junction temperature, T_J		+150°C
Storage temperature range, T_{stg}		–65°C to +150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		+260°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under*recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq +25°C$ POWER RATING
D (8)	38.3	176	710mW
D (14)	26.9	122.3	1022mW
D (16)	25.7	114.7	1090mW
DBV (5)	55	324.1	385mW
DBV (6)	55	294.3	425mW
DGN (8)	4.7	52.7	2.37W
DGQ (10)	4.7	52.3	2.39W
N (14, 16)	32	78	1600mW
P (8)	41	104	1200mW
PWP (14)	2.07	30.7	4.07W
PWP (16)	2.07	29.7	4.21W

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply	2.7	6	V
	Split supply	±1.35	±3	
Common-mode input voltage range, V_{ICR}		0	V_{DD}	V
Operating free-air temperature, T_A	C-suffix	0	+70	°C
	I-suffix	–40	+125	
Shutdown on/off voltage level(1)	V_{IH}	2		V
	V_{IL}		0.8	

(1) Relative to GND.

ELECTRICAL CHARACTERISTICS

At specified free-air temperature, V_{DD} = 3V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_S = 50\Omega$	TLV247x	+25°C		250	2200	µV
				Full range			2400	
			TLV247xA	+25°C		250	1600	
				Full range			1800	
α_{VIO}	Temperature coefficient of input offset voltage					0.4		µV/°C
I_{IO}	Input offset current			25°C		1.5	50	pA
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
I_{IB}	Input bias current			+25°C		2	50	
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
V_{OH}	High-level output voltage	$V_{IC} = V_{DD}/2$	I_{OH} = –2.5mA	+25°C	2.85	2.94		V
				Full range	2.8			
			I_{OH} = –10mA	+25°C	2.6	2.74		
				Full range	2.5			
V_{OL}	Low-level output voltage	$V_{IC} = V_{DD}/2$	I_{OL} = 2.5mA	+25°C		0.07	0.15	V
				Full range			0.2	
			I_{OL} = 10mA	+25°C		0.2	0.35	
				Full range			0.5	
I_{OS}	Short-circuit output current	Sourcing		+25°C	30			mA
				Full range	20			
		Sinking		+25°C	30			
				Full range	20			
I_O	Output current	V_O = 0.5V from rail		+25°C		±22		mA
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)}$ = 1V, R_L = 10kΩ		+25°C	90	116		dB
				Full range	88			
$r_{i(d)}$	Differential input resistance			+25°C		10^{12}		Ω
C_{IC}	Common-mode input capacitance	f = 10kHz		+25°C		19.3		pF
z_o	Closed-loop output impedance	f = 10kHz, A_V = 10		+25°C		2		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0V to 3V, R_S = 50Ω		+25°C	61	78		dB
			TLV247xC	Full range	59			
			TLV247xI	Full range	58			

(1) Full range is 0°C to +70°C for C-suffix and –40°C to +125°C for I-suffix. If not specified, full range is –40°C to +125°C.

ELECTRICAL CHARACTERISTICS (continued)

At specified free-air temperature, V_{DD} = 3V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 2.7V to 6V, V_{IC} = V_{DD}/2, No load		+25°C	74	90		dB
				Full range	66			
		V_{DD} = 3V to 5V, V_{IC} = V_{DD}/2, No load		+25°C	77	92		
				Full range	68			
I_{DD}	Supply current (per channel)	V_O = 1.5V, No load		+25°C		550	750	µA
				Full range			800	
$I_{DD(SHDN)}$	Supply current in shutdown mode (TLV2470, TLV2473, TLV2475) (per channel)	$\overline{SHDN}$ = 0V		+25°C		350	1500	nA
			TLV247xC	Full range			2000	
			TLV247xI	Full range			4000	

(1) Full range is 0°C to +70°C for C-suffix and –40°C to +125°C for I-suffix. If not specified, full range is –40°C to +125°C.

OPERATING CHARACTERISTICS

At specified free-air temperature, V_{DD} = 3V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_{O(PP)}$ = 0.8V, C_L = 150pF, R_L= 10kΩ		+25°C	1.1	1.4		V/µs
				Full range	0.6			
V_n	Equivalent input noise voltage	f = 100Hz		+25°C		28		nV/√Hz
		f = 1kHz		+25°C		15		
I_n	Equivalent input noise current	f = 1kHz		+25°C		0.405		pA/√Hz
THD+N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 2V, R_L= 10kΩ, f = 1kHz	A_V = 1	+25°C		0.02%		
			A_V = 10			0.1%		
			A_V = 100			0.5%		
$t_{(on)}$	Amplifier turn-on time	R_L= OPEN (2)		+25°C		5		µs
$t_{(off)}$	Amplifier turn-off time			+25°C		250		ns
	Gain-bandwidth product	f = 10kHz, R_L = 600Ω		+25°C		2.8		MHz
t_s	Settling time	$V_{(STEP)PP}$ = 2V, A_V = –1, C_L = 10pF, R_L = 10kΩ	0.1%	+25°C		1.5		µs
			0.01%			3.9		
		$V_{(STEP)PP}$ = 2V, A_V = –1, C_L = 56pF, R_L = 10kΩ	0.1%			1.6		
			0.01%			4		
Φ_m	Phase margin	R_L = 10kΩ, C_L = 1000pF		+25°C		61		°
	Gain margin	R_L = 10kΩ, C_L = 1000pF		+25°C		15		dB

(1) Full range is 0°C to +70°C for C-suffix and –40°C to +125°C for I-suffix. If not specified, full range is –40°C to +125°C.
(2) Disable and enable time are defined as the interval between application of logic signal to $\overline{SHDN}$ and the point at which the supply current has reached half its final value.

ELECTRICAL CHARACTERISTICS

At specified free-air temperature, V_{DD} = 5V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_S = 50\Omega$	TLV247x	+25°C		250	2200	μV
				Full range			2400	
			TLV247xA	+25°C		250	1600	
				Full range			2000	
α_{VIO}	Temperature coefficient of input offset voltage					0.4		μV/°C
I_{IO}	Input offset current			+25°C		1.7	50	pA
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
I_{IB}	Input bias current			+25°C		2.5	50	
			TLV247xC	Full range			100	
			TLV247xI	Full range			300	
V_{OH}	High-level output voltage	$V_{IC} = V_{DD}/2$	I_{OH} = –2.5mA	+25°C	4.85	4.96		V
				Full range	4.8			
			I_{OH} = –10mA	+25°C	4.72	4.82		
				Full range	4.65			
V_{OL}	Low-level output voltage	$V_{IC} = V_{DD}/2$	I_{OL} = 2.5mA	+25°C		0.07	0.15	V
				Full range			0.2	
			I_{OL} = 10mA	+25°C		0.178	0.28	
				Full range			0.35	
I_{OS}	Short-circuit output current	Sourcing		+25°C	110			mA
				Full range	60			
		Sinking		+25°C	90			
				Full range	60			
I_O	Output current	V_O = 0.5V from rail		+25°C		±35		mA
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)}$ = 3V, R_L = 10kΩ		+25°C	92	120		dB
				Full range	91			
$r_{i(d)}$	Differential input resistance			+25°C		10^{12}		Ω
C_{IC}	Common-mode input capacitance	f = 10kHz		+25°C		18.9		pF
z_o	Closed-loop output impedance	f = 10kHz, A_V = 10		+25°C		1.8		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0V to 5V, R_S = 50Ω		+25°C	64	84		dB
			TLV247xC	Full range	63			
			TLV247xI	Full range	58			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 2.7V to 6V, $V_{IC} = V_{DD}/2$, No load		+25°C	74	90		dB
				Full range	66			
		V_{DD} = 3V to 5V, $V_{IC} = V_{DD}/2$, No load		+25°C	77	92		
				Full range	66			
I_{DD}	Supply current (per channel)	V_O = 2.5V, No load		+25°C		600	900	μA
				Full range			1000	

(1) Full range is 0°C to +70°C for C-suffix and –40°C to +125°C for I-suffix. If not specified, full range is –40°C to +125°C.

ELECTRICAL CHARACTERISTICS (continued)

At specified free-air temperature, V_{DD} = 5V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
$I_{DD(SHDN)}$	Supply current in shutdown mode (TLV2470, TLV2473, TLV2475) (per channel)	$\overline{SHDN}$ = 0V		+25°C		1000	2500	nA
			TLV247xC	Full range			3000	
			TLV247xI	Full range			6000	nA

(1) Full range is 0°C to +70°C for C-suffix and –40°C to +125°C for I-suffix. If not specified, full range is –40°C to +125°C.

OPERATING CHARACTERISTICS

At specified free-air temperature, V_{DD} = 5V, unless otherwise noted.

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_{O(PP)}$ = 2V, C_L = 150pF, R_L= 10kΩ		+25°C	1.1	1.5		V/μs
				Full range	0.7			
V_n	Equivalent input noise voltage	f = 100Hz		+25°C		28		nV/√Hz
		f = 1kHz		+25°C		15		
I_n	Equivalent input noise current	f = 1kHz		+25°C		0.39		pA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = 4V, R_L= 10kΩ, f = 1kHz	A_V = 1	+25°C		0.01%		
			A_V = 10			0.05%		
			A_V = 100			0.3%		
$t_{(on)}$	Amplifier turn-on time	R_L= OPEN (2)		+25°C		5		μs
$t_{(off)}$	Amplifier turn-off time			+25°C		250		ns
	Gain-bandwidth product	f = 10kHz, R_L = 600Ω		+25°C		2.8		MHz
t_s	Settling time	$V_{(STEP)PP}$ = 2V, A_V = –1, C_L = 10pF, R_L = 10kΩ	0.1%	+25°C		1.8		μs
			0.01%			3.3		
		$V_{(STEP)PP}$ = 2V, A_V = –1, C_L = 56pF, R_L = 10kΩ	0.1%			1.7		
			0.01%			3		
Φ_m	Phase margin	R_L = 10kΩ, C_L = 1000pF		+25°C		68		°C
	Gain margin	R_L = 10kΩ, C_L = 1000pF		+25°C		23		dB

(1) Full range is 0°C to +70°C for C suffix and –40°C to +125°C for I suffix. If not specified, full range is –40°C to +125°C.
(2) Disable and enable time are defined as the interval between application of logic signal to $\overline{SHDN}$ and the point at which the supply current has reached half its final value.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	Figure 1, Figure 2
I_{IB}	Input bias current	vs Free-air temperature	Figure 3, Figure 4
I_{IO}	Input offset current		
V_{OH}	High-level output voltage	vs High-level output current	Figure 5, Figure 7
V_{OL}	Low-level output voltage	vs Low-level output current	Figure 6, Figure 8
Z_o	Output impedance	vs Frequency	Figure 9
I_{DD}	Supply current	vs Supply voltage	Figure 10
PSRR	Power-supply rejection ratio	vs Frequency	Figure 11
CMRR	Common-mode rejection ratio	vs Frequency	Figure 12
V_n	Equivalent input noise voltage	vs Frequency	Figure 13
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	Figure 14, Figure 15
A_{VD}	Differential voltage gain and phase	vs Frequency	Figure 16, Figure 17
Φ_m	Phase margin	vs Load capacitance	Figure 18, Figure 19
	Gain margin	vs Load capacitance	Figure 20, Figure 21
	Gain-bandwidth product	vs Supply voltage	Figure 22
SR	Slew rate	vs Supply voltage	Figure 23
		vs Free-air temperature	Figure 24, Figure 25
	Crosstalk	vs Frequency	Figure 26
THD+N	Total harmonic distortion + noise	vs Frequency	Figure 27, Figure 28
V_O	Large and small signal follower	vs Time	Figure 29–Figure 32
	Shutdown pulse response	vs Time	Figure 33, Figure 34
	Shutdown forward and reverse isolation	vs Frequency	Figure 35, Figure 36
$I_{DD(SHDN)}$	Shutdown supply current	vs Supply voltage	Figure 37
$I_{DD(SHDN)}$	Shutdown supply current	vs Free-air temperature	Figure 38
$I_{DD(SHDN)}$	Shutdown pulse current	vs Time	Figure 39, Figure 40

TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE vs COMMON-MODE INPUT VOLTAGE

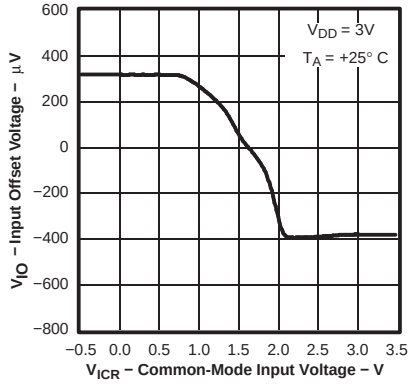


Figure 1.

INPUT OFFSET VOLTAGE vs COMMON-MODE INPUT VOLTAGE

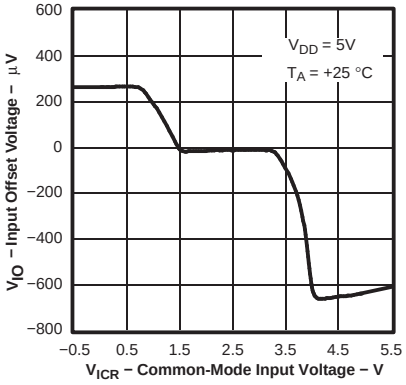


Figure 2.

INPUT BIAS AND INPUT OFFSET CURRENTS vs FREE-AIR TEMPERATURE

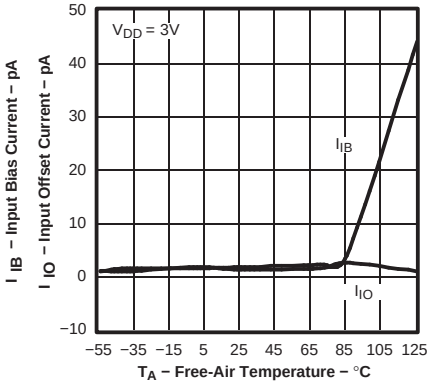


Figure 3.

INPUT BIAS AND INPUT OFFSET CURRENTS vs FREE-AIR TEMPERATURE

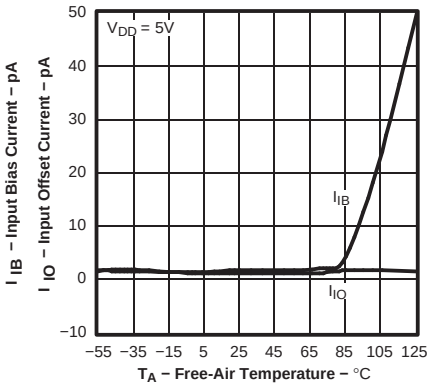


Figure 4.

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

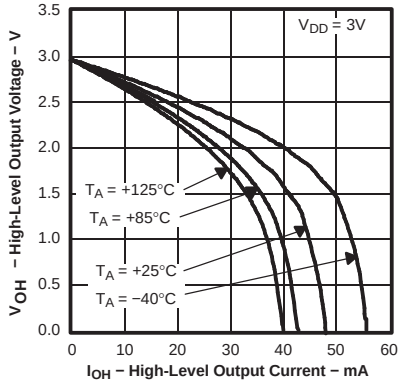


Figure 5.

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

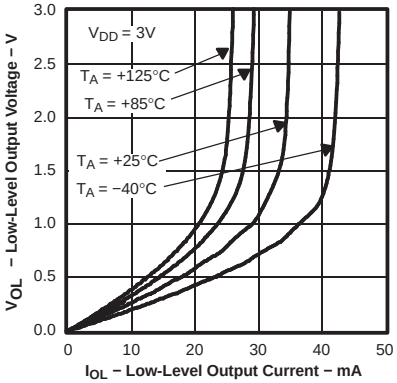


Figure 6.

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

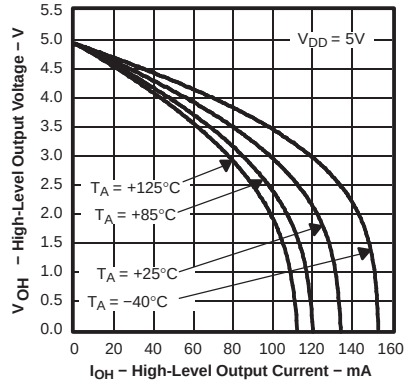


Figure 7.

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

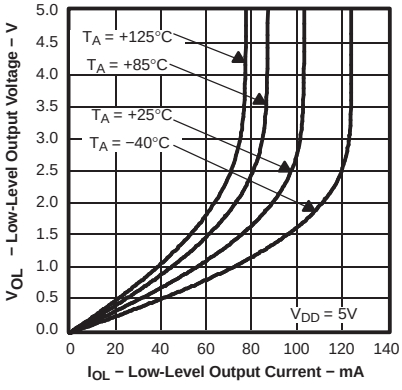


Figure 8.

OUTPUT IMPEDANCE vs FREQUENCY

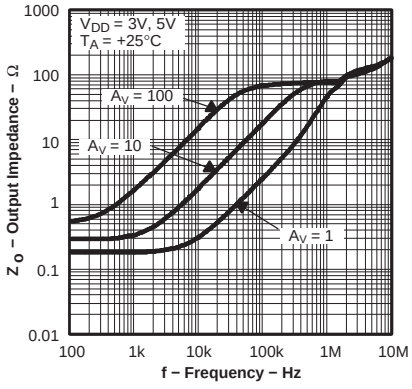


Figure 9.

TYPICAL CHARACTERISTICS (continued)

SUPPLY CURRENT vs SUPPLY VOLTAGE

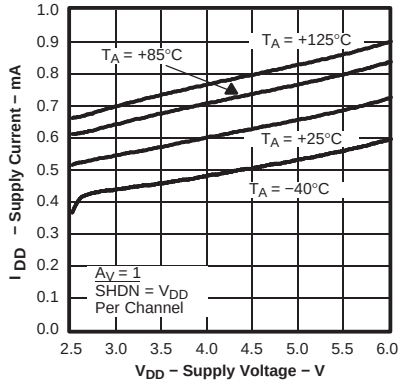


Figure 10.

POWER-SUPPLY REJECTION RATIO vs FREQUENCY

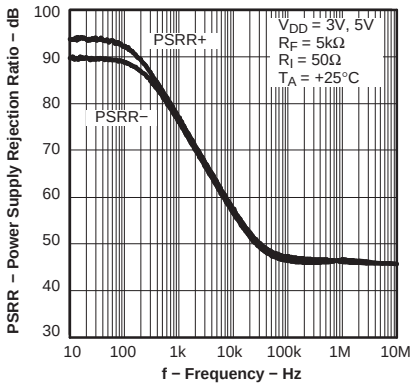


Figure 11.

COMMON-MODE REJECTION RATIO vs FREQUENCY

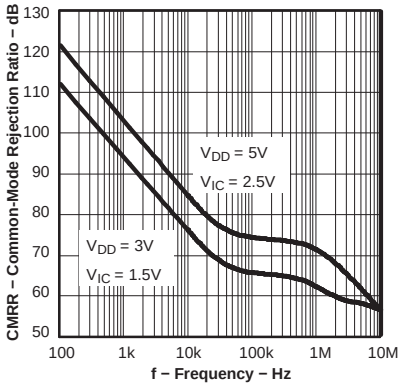


Figure 12.

EQUIVALENT NOISE VOLTAGE vs FREQUENCY

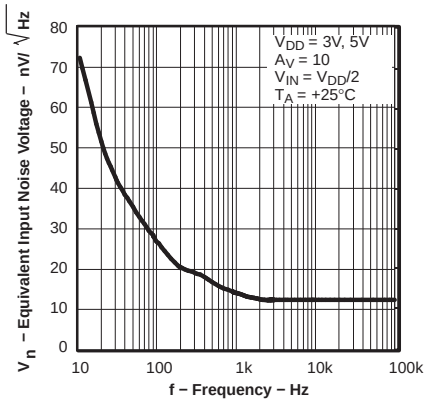


Figure 13.

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs FREQUENCY

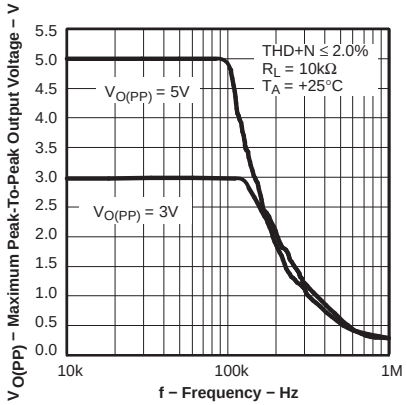


Figure 14.

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs FREQUENCY

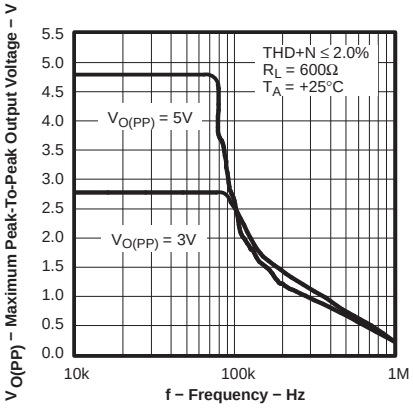


Figure 15.

DIFFERENTIAL VOLTAGE GAIN AND PHASE vs FREQUENCY

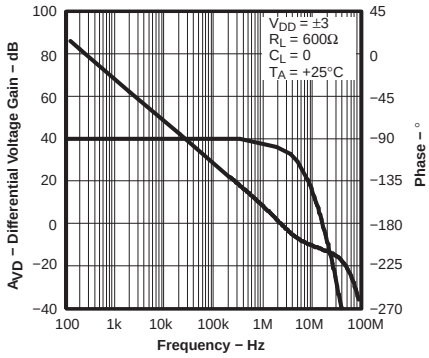


Figure 16.

DIFFERENTIAL VOLTAGE GAIN AND PHASE vs FREQUENCY

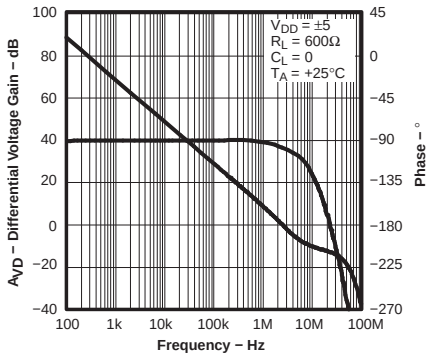


Figure 17.

TYPICAL CHARACTERISTICS (continued)

PHASE MARGIN vs LOAD CAPACITANCE

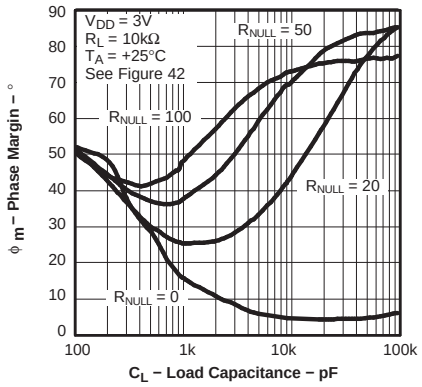


Figure 18.

PHASE MARGIN vs LOAD CAPACITANCE

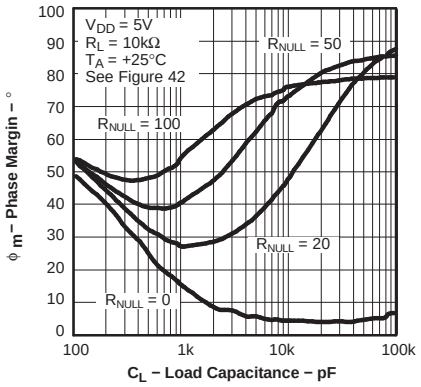


Figure 19.

GAIN MARGIN vs LOAD CAPACITANCE

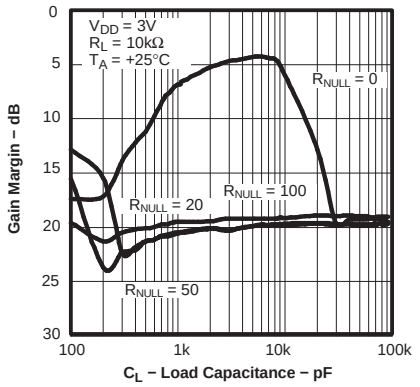


Figure 20.

GAIN MARGIN vs LOAD CAPACITANCE

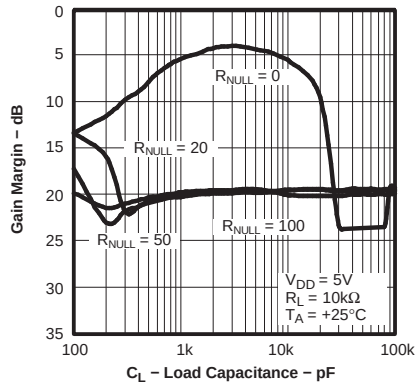


Figure 21.

GAIN-BANDWIDTH PRODUCT vs SUPPLY VOLTAGE

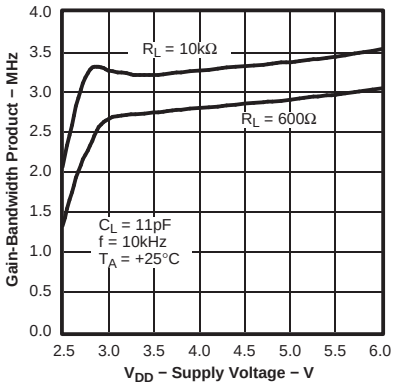


Figure 22.

SLEW RATE vs SUPPLY VOLTAGE

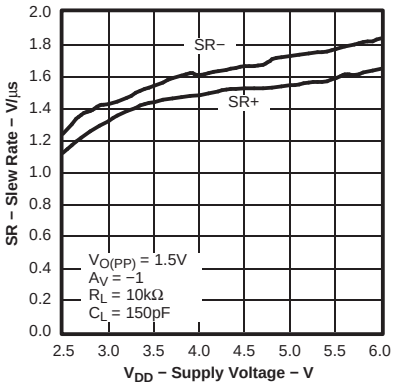


Figure 23.

SLEW RATE vs FREE-AIR TEMPERATURE

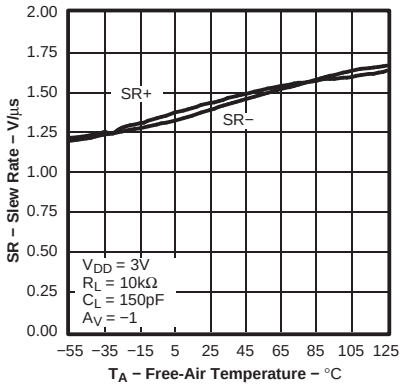


Figure 24.

SLEW RATE vs FREE-AIR TEMPERATURE

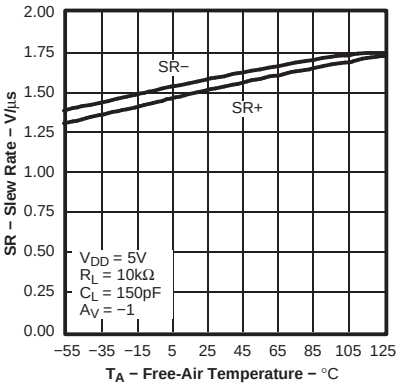


Figure 25.

TYPICAL CHARACTERISTICS (continued)

CROSSTALK vs FREQUENCY

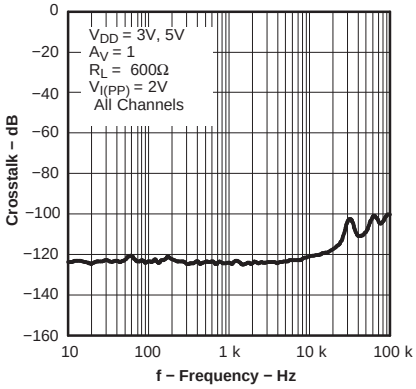


Figure 26.

TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY

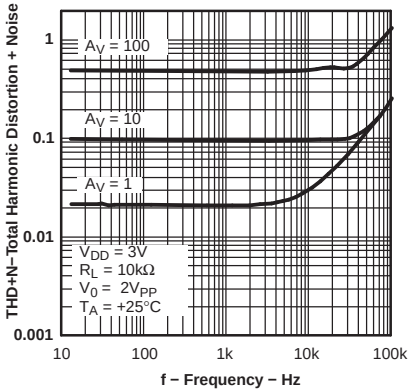


Figure 27.

TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY

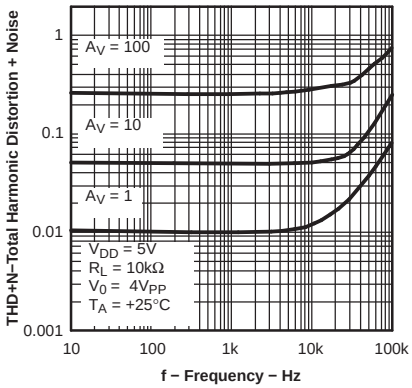


Figure 28.

LARGE-SIGNAL FOLLOWER PULSE RESPONSE vs TIME

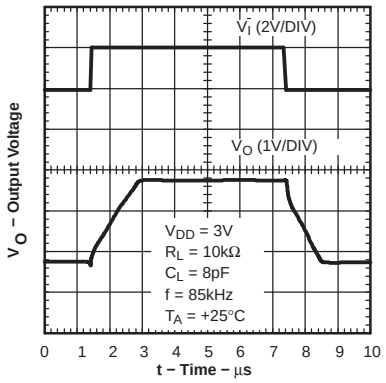


Figure 29.

LARGE-SIGNAL FOLLOWER PULSE RESPONSE vs TIME

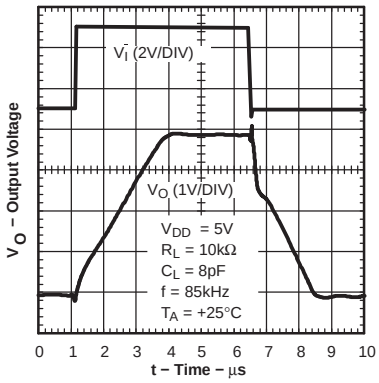


Figure 30.

SMALL-SIGNAL FOLLOWER PULSE RESPONSE vs TIME

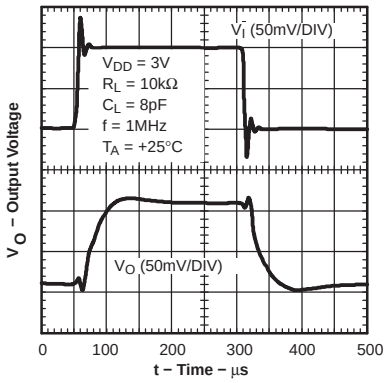


Figure 31.

SMALL-SIGNAL FOLLOWER PULSE RESPONSE vs TIME

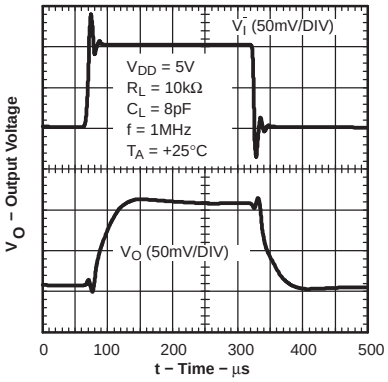


Figure 32.

SHUTDOWN (ON AND OFF) PULSE RESPONSE vs TIME

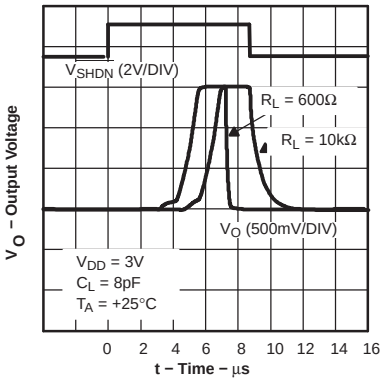


Figure 33.

SHUTDOWN (ON AND OFF) PULSE RESPONSE vs TIME

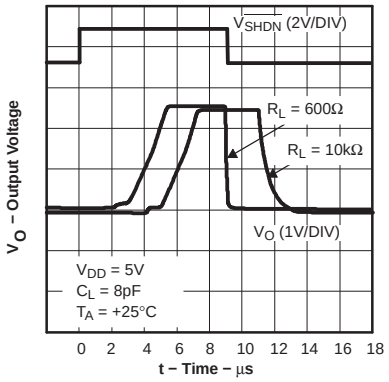


Figure 34.

TYPICAL CHARACTERISTICS (continued)

SHUTDOWN FORWARD ISOLATION vs FREQUENCY

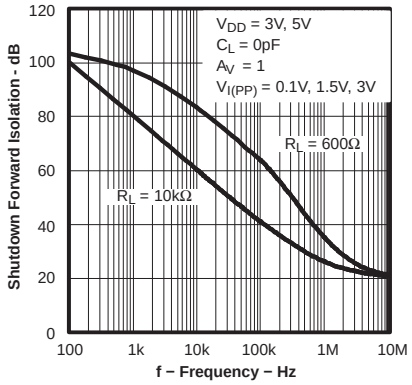


Figure 35.

SHUTDOWN REVERSE ISOLATION vs FREQUENCY

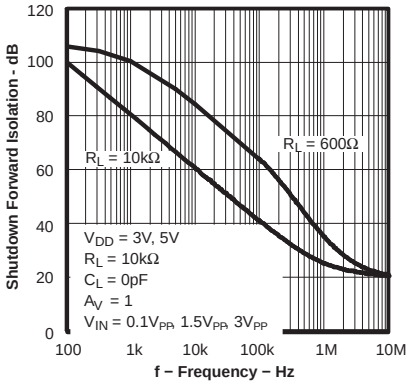


Figure 36.

SHUTDOWN SUPPLY CURRENT vs SUPPLY VOLTAGE

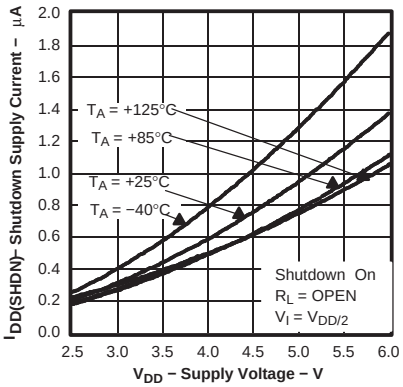


Figure 37.

SHUTDOWN SUPPLY CURRENT vs FREE-AIR TEMPERATURE

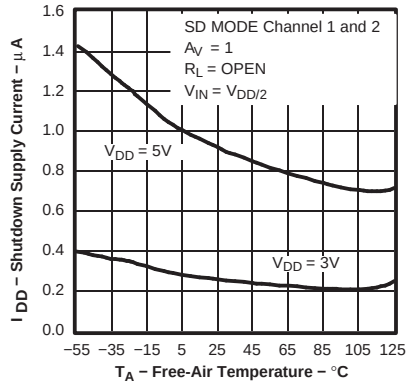


Figure 38.

SHUTDOWN PULSE CURRENT vs TIME

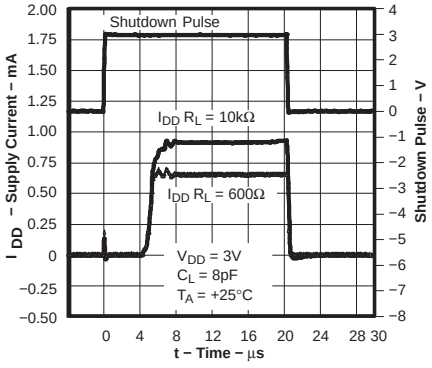


Figure 39.

SHUTDOWN PULSE CURRENT vs TIME

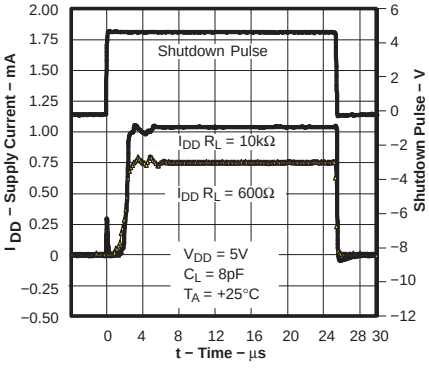


Figure 40.

PARAMETER MEASUREMENT INFORMATION

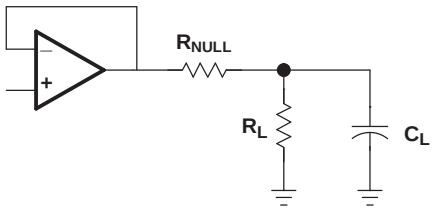


Figure 41.

APPLICATION INFORMATION

DRIVING A CAPACITIVE LOAD

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device phase margin leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10pF, it is recommended that a resistor (R_{NULL}) be placed in series with the output of the amplifier, as shown in Figure 42. A minimum value of 20Ω should work well for most applications.

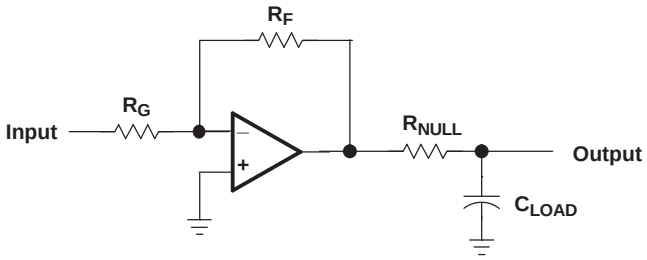
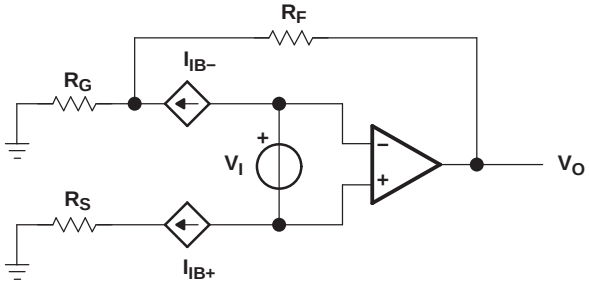


Figure 42. Driving a Capacitive Load

OFFSET VOLTAGE

The output offset voltage (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:



$$V_{OO} = V_{IO}\left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB+} R_S \left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB-} R_F$$

Figure 43. Output Offset Voltage Model

APPLICATION INFORMATION (continued)

GENERAL CONFIGURATIONS

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 44).

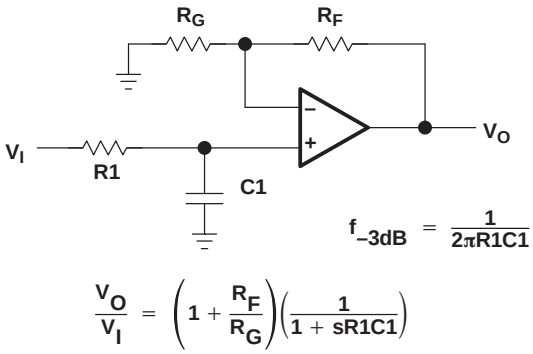


Figure 44. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is eight to ten times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

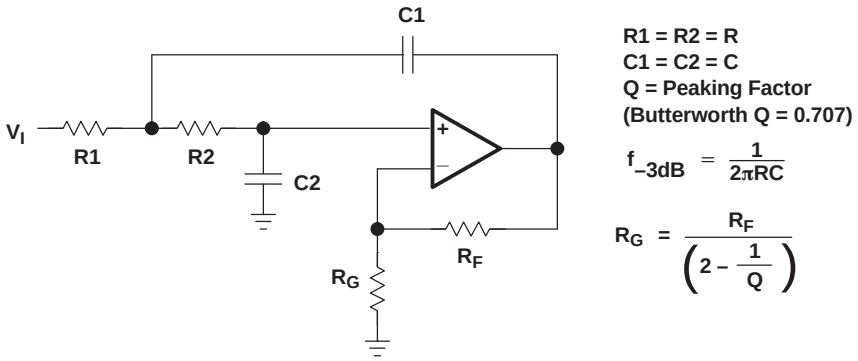


Figure 45. 2-Pole Low-Pass Sallen-Key Filter

SHUTDOWN FUNCTION

Three members of the TLV247x family (TLV2470/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 350nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to $V_{DD}/2$. Therefore, when operating the device with split supply voltages (e.g., ±2.5V), the shutdown terminal needs to be pulled to V_{DD}– (not GND) to disable the operational amplifier.

The amplifier output with a shutdown pulse is shown in Figure 33 and Figure 34. The amplifier is powered with a single 5V supply and configured as a noninverting configuration with a gain of 5. The amplifier turn-on and turn-off times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad versions are listed in the data tables.

APPLICATION INFORMATION (continued)

Figure 35 and Figure 36 show the amplifier forward and reverse isolation in shutdown. The operational amplifier is powered by ±1.35V supplies and configured as a voltage follower (A_V= 1). The isolation performance is plotted across frequency using $0.1V_{PP}$, $1.5V_{PP}$, and $2.5V_{PP}$ input signals. During normal operation, the amplifier would not be able to handle a $2.5V_{PP}$ input signal with a supply voltage of ±1.35V since it exceeds the common-mode input voltage range (V_{ICR}). However, this curve illustrates that the amplifier remains in shutdown even under a worst case scenario.

CIRCUIT LAYOUT CONSIDERATIONS

To achieve the levels of high performance of the TLV247x, follow proper printed circuit board (PCB) design techniques. A general set of guidelines is given below:

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8μF tantalum capacitor in parallel with a 0.1μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high-performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

GENERAL PowerPAD™ DESIGN CONSIDERATIONS

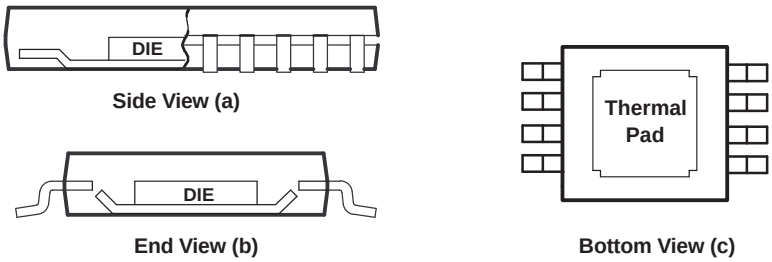
The TLV247x is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted (see Figure 46a and Figure 46b). This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package (see Figure 46c). Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad must be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

Soldering the PowerPAD to the PCB is always recommended, even with applications that have low power dissipation. It provides the necessary mechanical and thermal connection between the lead frame die pad and the PCB.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with previously awkward mechanical methods of heatsinking.

APPLICATION INFORMATION (continued)



The thermal pad is electrically isolated from all terminals in the package.

Figure 46. Views of Thermally Enhanced DGN Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

1. The thermal pad must be connected to the most negative supply voltage on the device (GND pin).
2. Prepare the PCB with a top side etch pattern as illustrated in the thermal land pattern mechanical drawing at the end of this document. There should be etch for the leads as well as etch for the thermal pad.
3. Place holes in the area of the thermal pad as illustrated in the land pattern mechanical drawing at the end of this document. These holes should be 13mils (0.013 inches or 0.3302mm) in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
4. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the TLV247x IC. These additional vias may be larger than the 13mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
5. Connect all holes to the internal ground plane that is at the same voltage potential as the device GND pin.
6. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the TLV247x PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
7. The top-side solder mask should leave the terminals of the package and the thermal pad area with its holes exposed. The bottom-side solder mask should cover the holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
8. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
9. With these preparatory steps in place, the TLV247x IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

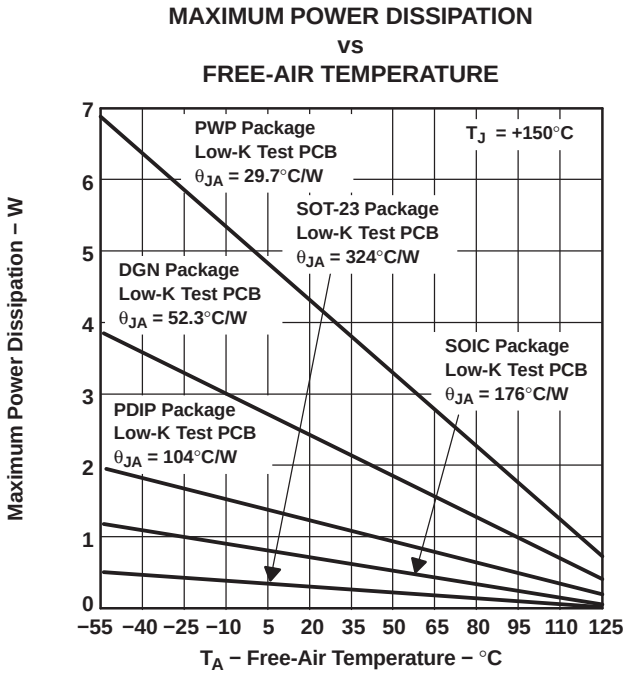
For a given θ_{JA}, the maximum power dissipation is shown in Figure 47 and is calculated by Equation 1:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right) \quad (1)$$

Where:

- P_D = Maximum power dissipation of TLV247x IC (watts)
- T_{MAX} = Absolute maximum junction temperature (+150°C)
- T_A = Free-ambient air temperature (°C)
- $\theta_{JA} = \theta_{JC} + \theta_{CA}$
  - θ_{JC} = Thermal coefficient from junction to case
  - θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

APPLICATION INFORMATION (continued)



Results are obtained with no air flow and using JEDEC Standard Low-K test PCB.

Figure 47. Maximum Power Dissipation vs Free-Air Temperature

The next consideration is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents. Figure 48 to Figure 53 show this effect, along with the quiescent heat, with an ambient air temperature of +70°C and +125°C. When using V_{DD} = 3V, there is generally not a heat problem with an ambient air temperature of +70°C. But, when using V_{DD} = 5V, the package is severely limited in the amount of heat it can dissipate. The other key factor when looking at these graphs is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat dissipation. But the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual or quad amplifier packages, the sum of the RMS output currents and voltages should be used to choose the proper package.

APPLICATION INFORMATION (continued)

TLV2470, TLV2471(1)
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

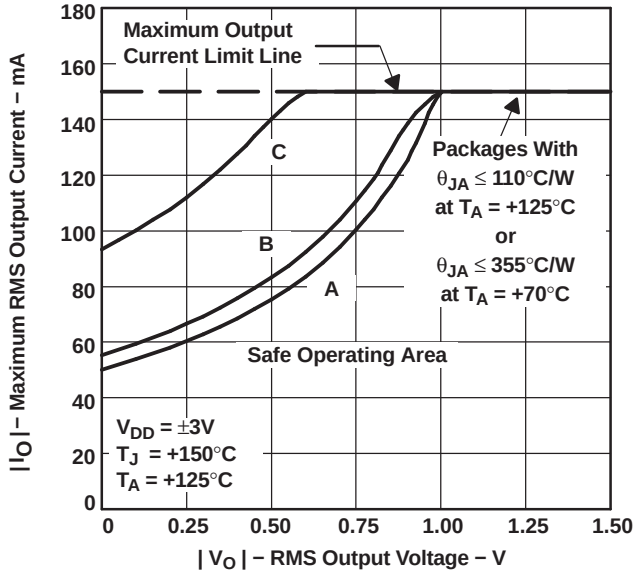


Figure 48.

TLV2470, TLV2471(1)
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

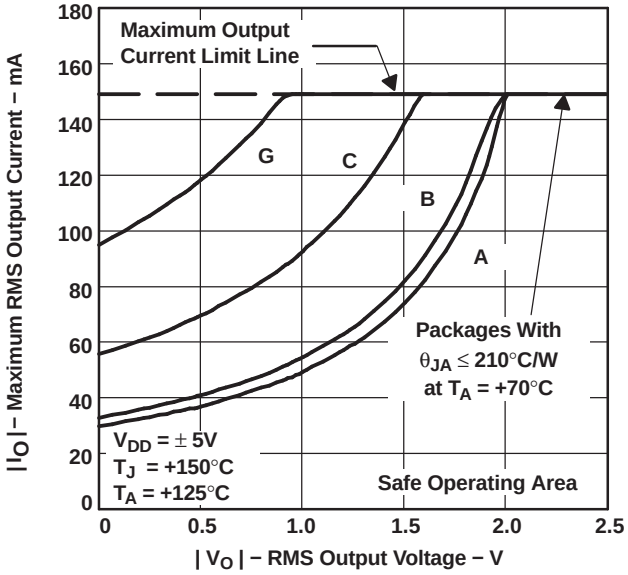


Figure 49.

TLV2472, TLV2473(1)
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

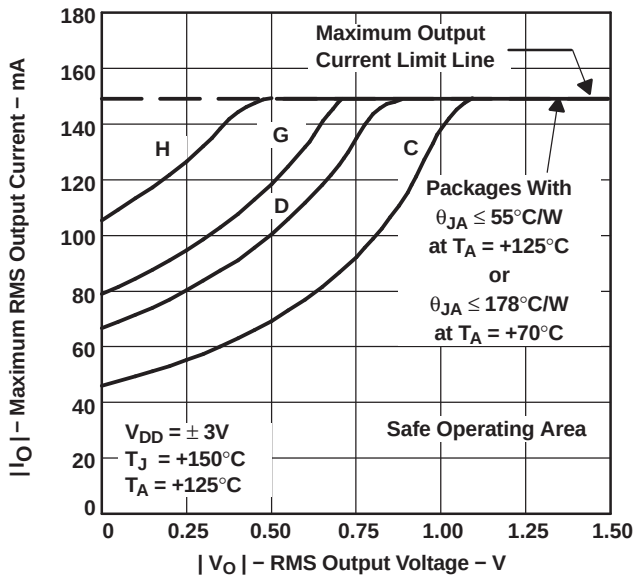


Figure 50.

TLV2472, TLV2473(1)
MAXIMUM RMS OUTPUT CURRENT
vs
RMS OUTPUT VOLTAGE DUE TO THERMAL LIMITS

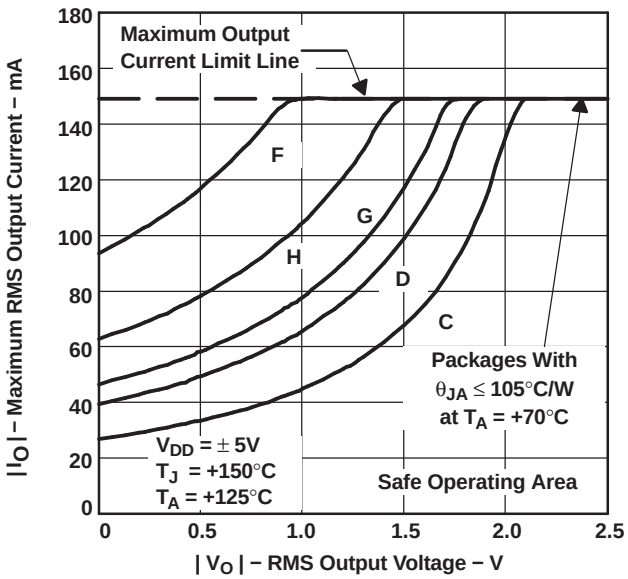


Figure 51.

Note: (1) A - SOT23 (5); B - SOT23 (6); C - SOIC (8); D - SOIC (14); E - SOIC (16); F - MSOP PP (8); G - PDIP (8); H - PDIP (14): I - PDIP (16); J - TSSOP PP (14/16)

APPLICATION INFORMATION (continued)

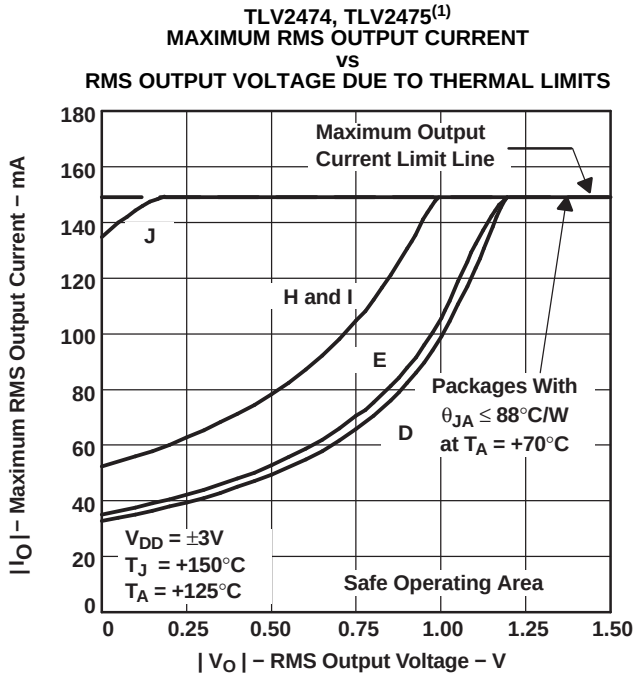


Figure 52.

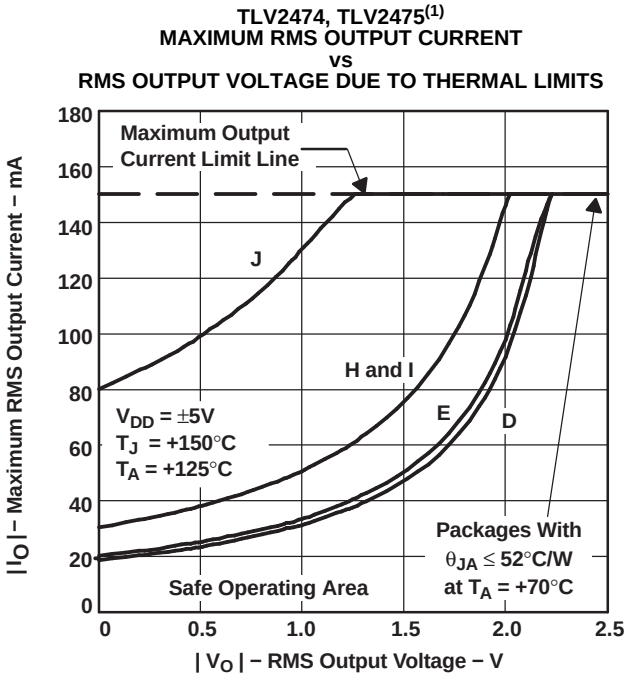


Figure 53.

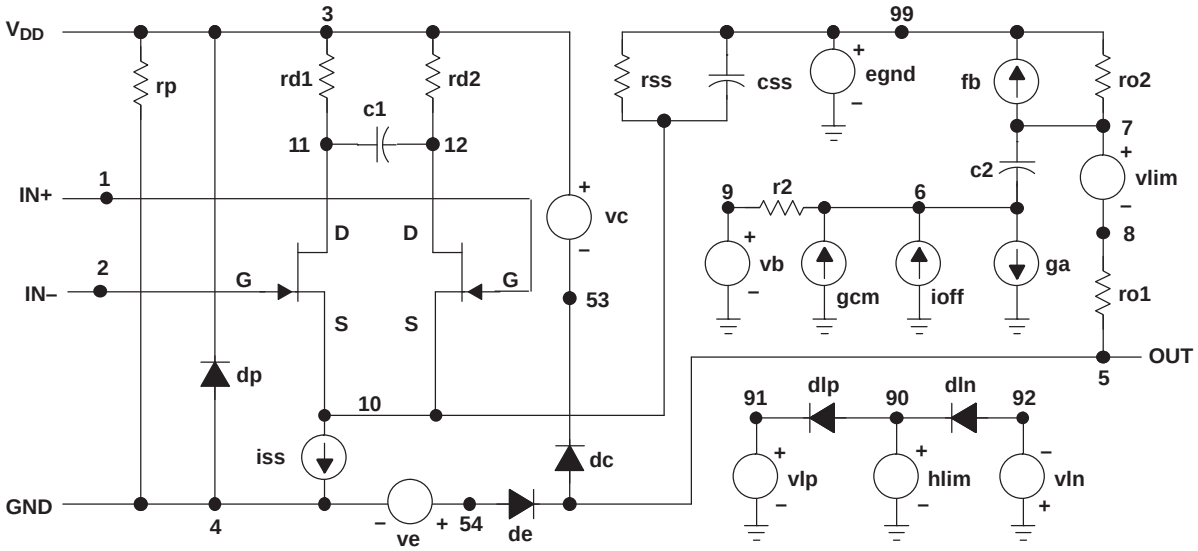
NOTE: (1) A - SOT23 (5); B - SOT23 (6); C - SOIC (8); D - SOIC (14); E - SOIC (16); F - MSOP PP (8); G - PDIP (8); H - PDIP (14): I - PDIP (16); J - TSSOP PP (14/16)

APPLICATION INFORMATION (continued)

MACROMODEL INFORMATION

Macromodel information provided was derived using Microsim PARTS™, the model generation software used with Microsim PSpice®. The Boyle macromodel and subcircuit in Figure 54 are generated using the TLV247x typical electrical and operating characteristics at T_A = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit




```
* TLV247x operational amplifier "macromodel" subcircuit
* created using Parts release 8.0 on 4/27/99 at 14:31
* Parts is a MicroSim product.
*
* connections:   non–inverting input
*                | inverting input
*                | | positive power supply
*                | | | negative power supply
*                | | | | output
*                | | | | |
.subckt  TLV247x 1 2 3 4 5
*
c1          11      12      1.1094E–12
c2          6       7       5.5000E–12
css         10      99      556.53E–15
dc          5       53      dy
de          54      5       dy
dlp         90      91      dx
dln         92      90      dx
dp          4       3       dx
egnd        99      0       poly(2) (3,0) (4,0) 0 .5 .5
fb          7       99      poly(5) vb vc ve vlp vln 0
+ 39.614E6 –1E3 1E3 40E6 –40E6
ga          6       0       11      12      79.828E–6
gcm         0       6       10      99      32.483E–9
iss         10      4       dc      10.714E–6
hlim        90      0       vlim 1K
ioff        0       6       dc      75E–9
j1          11      2       10 jx1
j2          12      1       10 jx2
r2          6       9       100.00E3
rd1         3       11      12.527E3
rd2         3       12      12.527E3
ro1         8       5       10
ro2         7       99      10
rp          3       4       3.8023E3
rss         10      99      18.667E6
vb          9       0       dc 0
vc          3       53      dc .842
ve          54      4       dc .842
vlim        7       8       dc 0
vlp         91      0       dc 110
vln         0       92      dc 110
.model      dx      D(Is=800.00E–18)
.model      dy      D(Is=800.00E–18 Rs=1m Cjo=10p)
.model      jx1     NJF(Is=1.0825E–12 Beta=594.78E–06 + Vto=–1)
.model      jx2     NJF(Is=1.0825E–12 Beta=594.78E–06 + Vto=–1)
.ends
*$
```

G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers, "*IEEE Journal of Solid-State Circuits,* SC-9, 353 (1974).

Figure 54. Boyle Macromodel and Subcircuit

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2470AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470AI	Samples
TLV2470AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470AI	Samples
TLV2470AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470AI	Samples
TLV2470AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470AI	Samples
TLV2470AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2470AI	Samples
TLV2470AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2470AI	Samples
TLV2470CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2470C	Samples
TLV2470CDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAUC	Samples
TLV2470CDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAUC	Samples
TLV2470CDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAUC	Samples
TLV2470CDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAUC	Samples
TLV2470CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2470C	Samples
TLV2470CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2470C	Samples
TLV2470CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2470C	Samples
TLV2470CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2470C	Samples
TLV2470CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2470C	Samples
TLV2470ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2470IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAUI	Samples
TLV2470IDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAUI	Samples
TLV2470IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAUI	Samples
TLV2470IDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAUI	Samples
TLV2470IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470I	Samples
TLV2470IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470I	Samples
TLV2470IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2470I	Samples
TLV2471AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471AI	Samples
TLV2471AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471AI	Samples
TLV2471AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471AI	Samples
TLV2471AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471AI	Samples
TLV2471AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2471AI	Samples
TLV2471AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2471AI	Samples
TLV2471CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2471C	Samples
TLV2471CDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAVC	Samples
TLV2471CDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAVC	Samples
TLV2471CDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAVC	Samples
TLV2471CDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VAVC	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2471CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2471C	Samples
TLV2471CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2471C	Samples
TLV2471CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2471C	Samples
TLV2471CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2471C	Samples
TLV2471CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2471C	Samples
TLV2471ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471I	Samples
TLV2471IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAVI	Samples
TLV2471IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAVI	Samples
TLV2471IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAVI	Samples
TLV2471IDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAVI	Samples
TLV2471IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471I	Samples
TLV2471IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471I	Samples
TLV2471IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2471I	Samples
TLV2471IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2471I	Samples
TLV2471IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2471I	Samples
TLV2472AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472AI	Samples
TLV2472AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472AI	Samples
TLV2472AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472AI	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2472AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472AI	Samples
TLV2472AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2472AI	Samples
TLV2472AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2472AI	Samples
TLV2472CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2472C	Samples
TLV2472CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2472C	Samples
TLV2472CDGN	ACTIVE	MSOP-PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABU	Samples
TLV2472CDGNG4	ACTIVE	MSOP-PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABU	Samples
TLV2472CDGNR	ACTIVE	MSOP-PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABU	Samples
TLV2472CDGNRG4	ACTIVE	MSOP-PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABU	Samples
TLV2472CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2472C	Samples
TLV2472CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2472C	Samples
TLV2472CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2472CP	Samples
TLV2472CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2472CP	Samples
TLV2472ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472I	Samples
TLV2472IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472I	Samples
TLV2472IDGN	ACTIVE	MSOP-PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABV	Samples
TLV2472IDGNG4	ACTIVE	MSOP-PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABV	Samples
TLV2472IDGNR	ACTIVE	MSOP-PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABV	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2472IDGNRG4	ACTIVE	MSOP-PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABV	Samples
TLV2472IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472I	Samples
TLV2472IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2472I	Samples
TLV2472IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2472IP	Samples
TLV2472IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2472IP	Samples
TLV2473AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2473AI	Samples
TLV2473AIDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2473AI	Samples
TLV2473AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2473AI	Samples
TLV2473AIDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2473AI	Samples
TLV2473AIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2473AIN	Samples
TLV2473AINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2473AIN	Samples
TLV2473CD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2473C	Samples
TLV2473CDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2473C	Samples
TLV2473CDGQR	ACTIVE	MSOP-PowerPAD	DGQ	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABW	Samples
TLV2473CDGQRG4	ACTIVE	MSOP-PowerPAD	DGQ	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ABW	Samples
TLV2473CDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2473C	Samples
TLV2473CDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2473C	Samples
TLV2473IDGQR	ACTIVE	MSOP-PowerPAD	DGQ	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABX	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2473IDGQRG4	ACTIVE	MSOP-PowerPAD	DGQ	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABX	Samples
TLV2473IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2473IN	Samples
TLV2473INE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2473IN	Samples
TLV2474AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2474AI	Samples
TLV2474AINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2474AI	Samples
TLV2474AIPWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474AI	Samples
TLV2474AIPWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474AI	Samples
TLV2474AIPWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474AI	Samples
TLV2474AIPWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474AI	Samples
TLV2474AIPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474AIPWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474AI	Samples
TLV2474CD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	0 to 70	2474C	Samples
TLV2474CDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	0 to 70	2474C	Samples
TLV2474CDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2474C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2474CDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2474C	Samples
TLV2474CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2474C	Samples
TLV2474CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2474C	Samples
TLV2474CPWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	2474C	Samples
TLV2474CPWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	2474C	Samples
TLV2474CPWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	2474C	Samples
TLV2474CPWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	2474C	Samples
TLV2474ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	2474I	Samples
TLV2474IDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	2474I	Samples
TLV2474IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474I	Samples
TLV2474IDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2474I	Samples
TLV2474IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2474I	Samples
TLV2474INE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2474I	Samples
TLV2474IPWP	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474I	Samples
TLV2474IPWPG4	ACTIVE	HTSSOP	PWP	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474I	Samples
TLV2474IPWPR	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474I	Samples
TLV2474IPWPRG4	ACTIVE	HTSSOP	PWP	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2474I	Samples
TLV2475AIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2475AI	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2475AIDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2475AI	Samples
TLV2475AIN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2475AI	Samples
TLV2475AINE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2475AI	Samples
TLV2475AIPWP	ACTIVE	HTSSOP	PWP	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475AI	Samples
TLV2475AIPWPG4	ACTIVE	HTSSOP	PWP	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475AI	Samples
TLV2475AIPWPR	ACTIVE	HTSSOP	PWP	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475AI	Samples
TLV2475AIPWPRG4	ACTIVE	HTSSOP	PWP	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475AI	Samples
TLV2475CD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2475C	Samples
TLV2475CDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2475C	Samples
TLV2475CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2475C	Samples
TLV2475CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2475C	Samples
TLV2475CN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2475C	Samples
TLV2475CNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLV2475C	Samples
TLV2475CPWPR	ACTIVE	HTSSOP	PWP	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	2475C	Samples
TLV2475CPWPRG4	ACTIVE	HTSSOP	PWP	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	2475C	Samples
TLV2475IDR	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 125	TLV2475I	
TLV2475IDRG4	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 125		
TLV2475IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2475I	Samples
TLV2475INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2475I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV2475IPWPR	ACTIVE	HTSSOP	PWP	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475I	Samples
TLV2475IPWPRG4	ACTIVE	HTSSOP	PWP	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	2475I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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OTHER QUALIFIED VERSIONS OF TLV2471, TLV2471A, TLV2472, TLV2472A, TLV2474, TLV2474A :

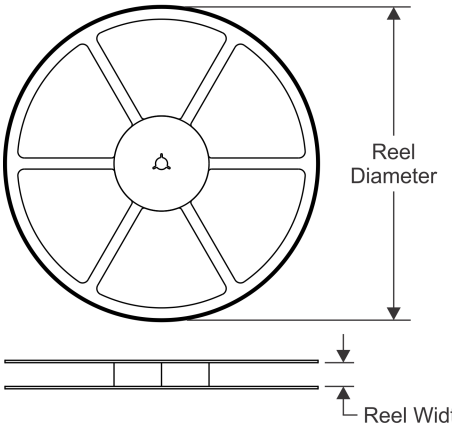
- Automotive: TLV2471-Q1, TLV2471A-Q1, TLV2472-Q1, TLV2472A-Q1, TLV2474-Q1, TLV2474A-Q1

NOTE: Qualified Version Definitions:

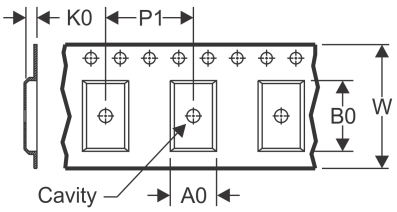
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

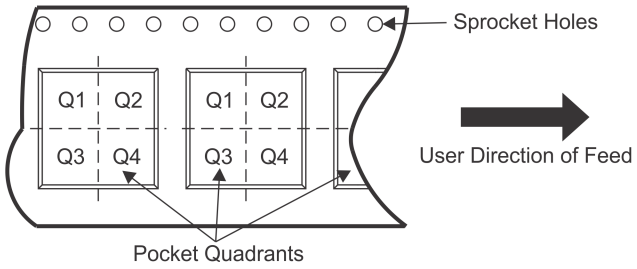


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

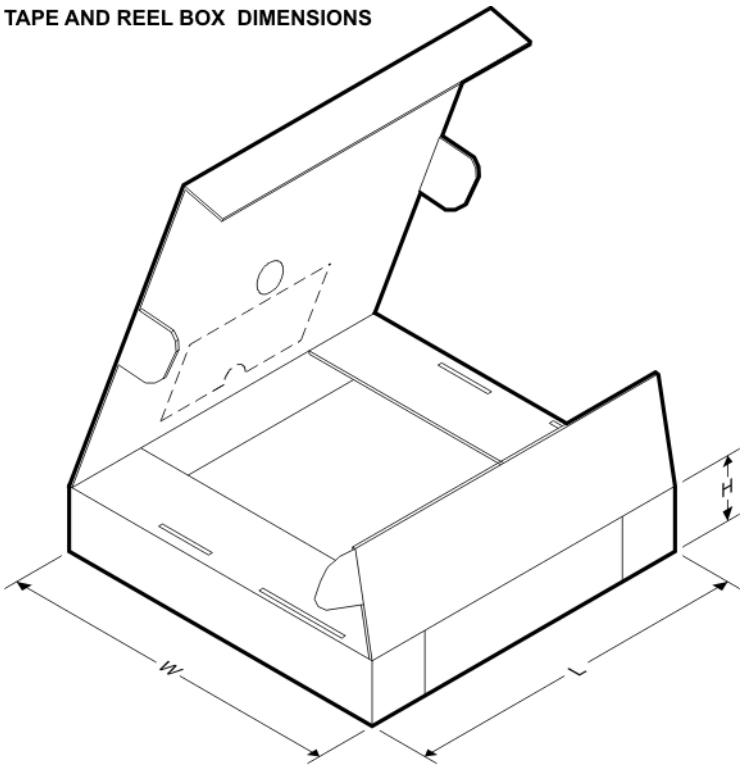


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2470AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2470CDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470CDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2470IDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470IDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2470IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2470IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2471AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2471CDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471CDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2471IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2471IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2472AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2472CDGNR	MSOP-Power	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	PAD											
TLV2472CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2472IDGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2472IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2473AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2473CDGQR	MSOP-Power PAD	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2473CDGQR	MSOP-Power PAD	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2473CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2473IDGQR	MSOP-Power PAD	DGQ	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2474AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2474AIPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2474AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2474CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2474CPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2474IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2474IPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2475AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2475AIPWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2475CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2475CPWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2475IPWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

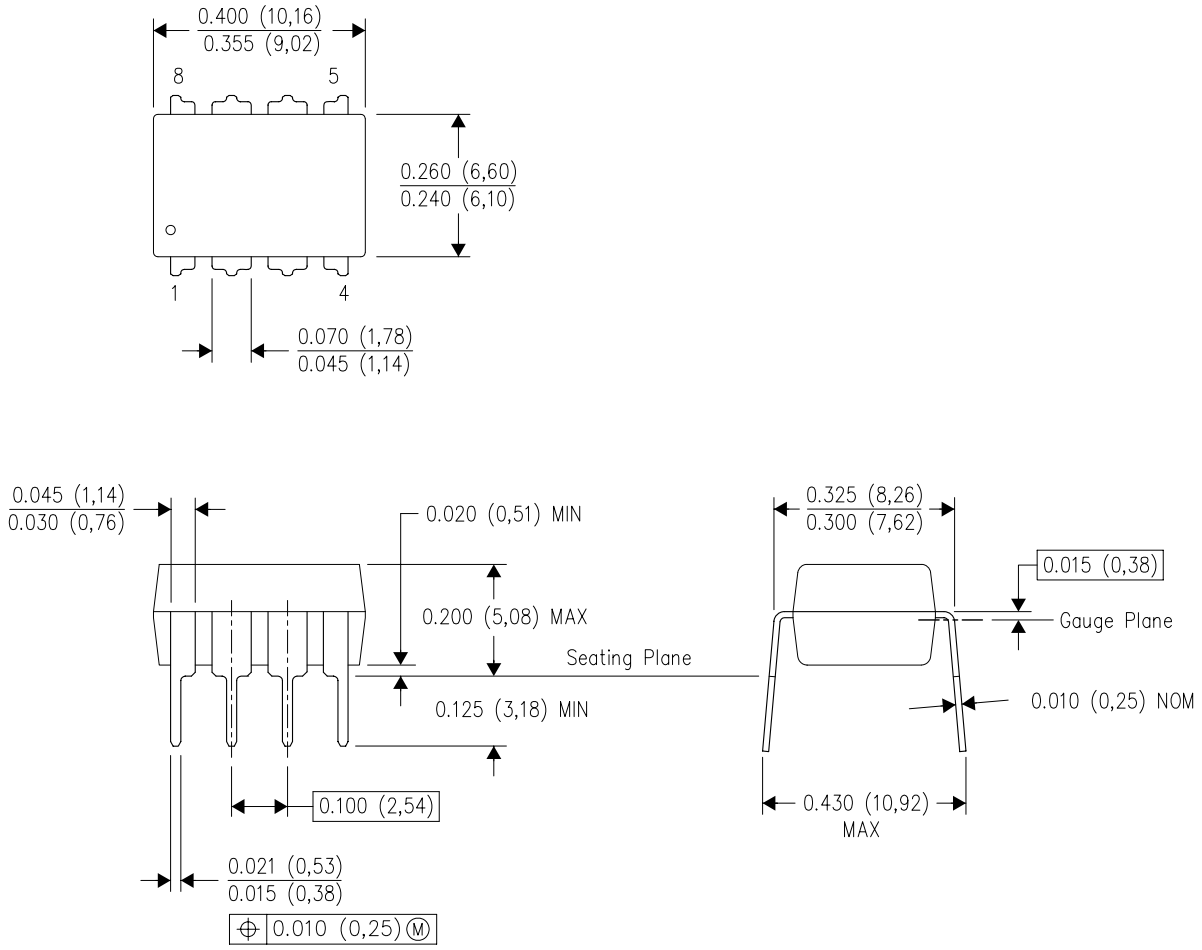


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2470AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2470CDBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TLV2470CDBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TLV2470CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2470IDBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TLV2470IDBVT	SOT-23	DBV	6	250	180.0	180.0	18.0
TLV2470IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2470IDR	SOIC	D	8	2500	367.0	367.0	35.0
TLV2471AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2471CDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2471CDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2471CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2471IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2471IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2471IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2472AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2472CDGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0
TLV2472CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2472IDGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0
TLV2472IDR	SOIC	D	8	2500	340.5	338.1	20.6

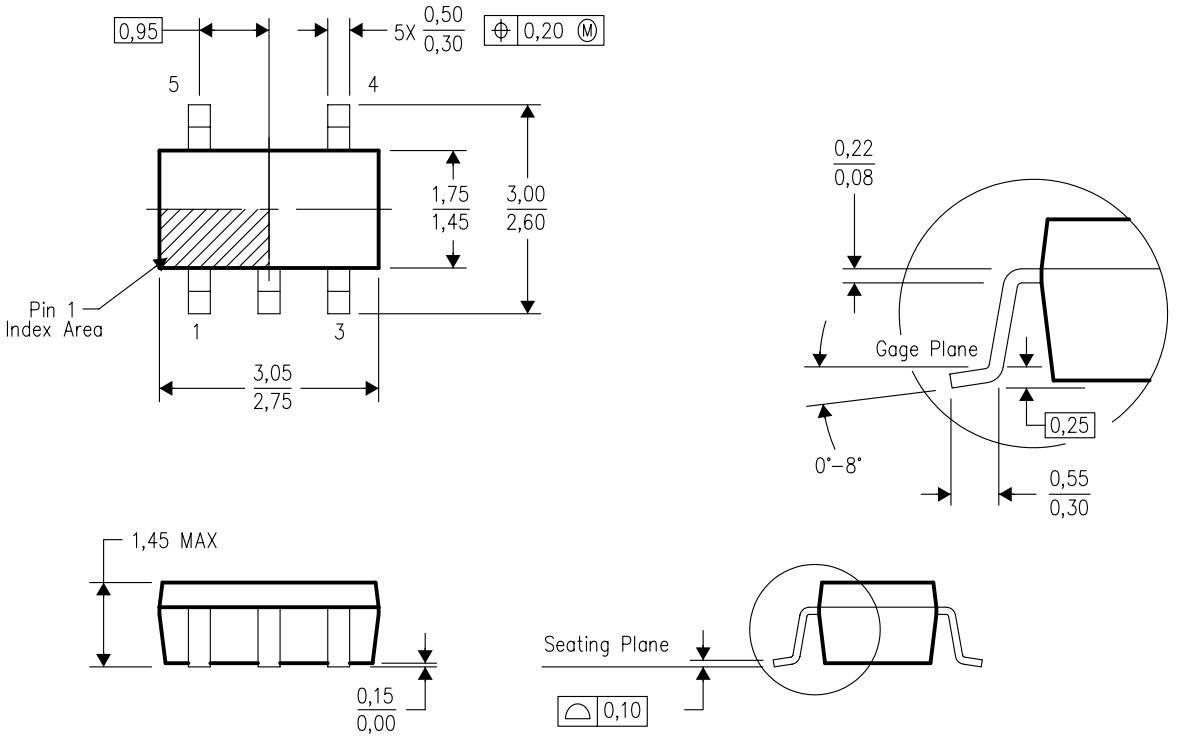
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2473AIDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2473CDGQR	MSOP-PowerPAD	DGQ	10	2500	358.0	335.0	35.0
TLV2473CDGQR	MSOP-PowerPAD	DGQ	10	2500	364.0	364.0	27.0
TLV2473CDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2473IDGQR	MSOP-PowerPAD	DGQ	10	2500	358.0	335.0	35.0
TLV2474AIDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2474AIPWPR	HTSSOP	PWP	14	2000	367.0	367.0	35.0
TLV2474AIPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TLV2474CDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2474CPWPR	HTSSOP	PWP	14	2000	367.0	367.0	35.0
TLV2474IDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2474IPWPR	HTSSOP	PWP	14	2000	367.0	367.0	35.0
TLV2475AIDR	SOIC	D	16	2500	367.0	367.0	38.0
TLV2475AIPWPR	HTSSOP	PWP	16	2000	367.0	367.0	35.0
TLV2475CDR	SOIC	D	16	2500	367.0	367.0	38.0
TLV2475CPWPR	HTSSOP	PWP	16	2000	367.0	367.0	35.0
TLV2475IPWPR	HTSSOP	PWP	16	2000	367.0	367.0	35.0

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

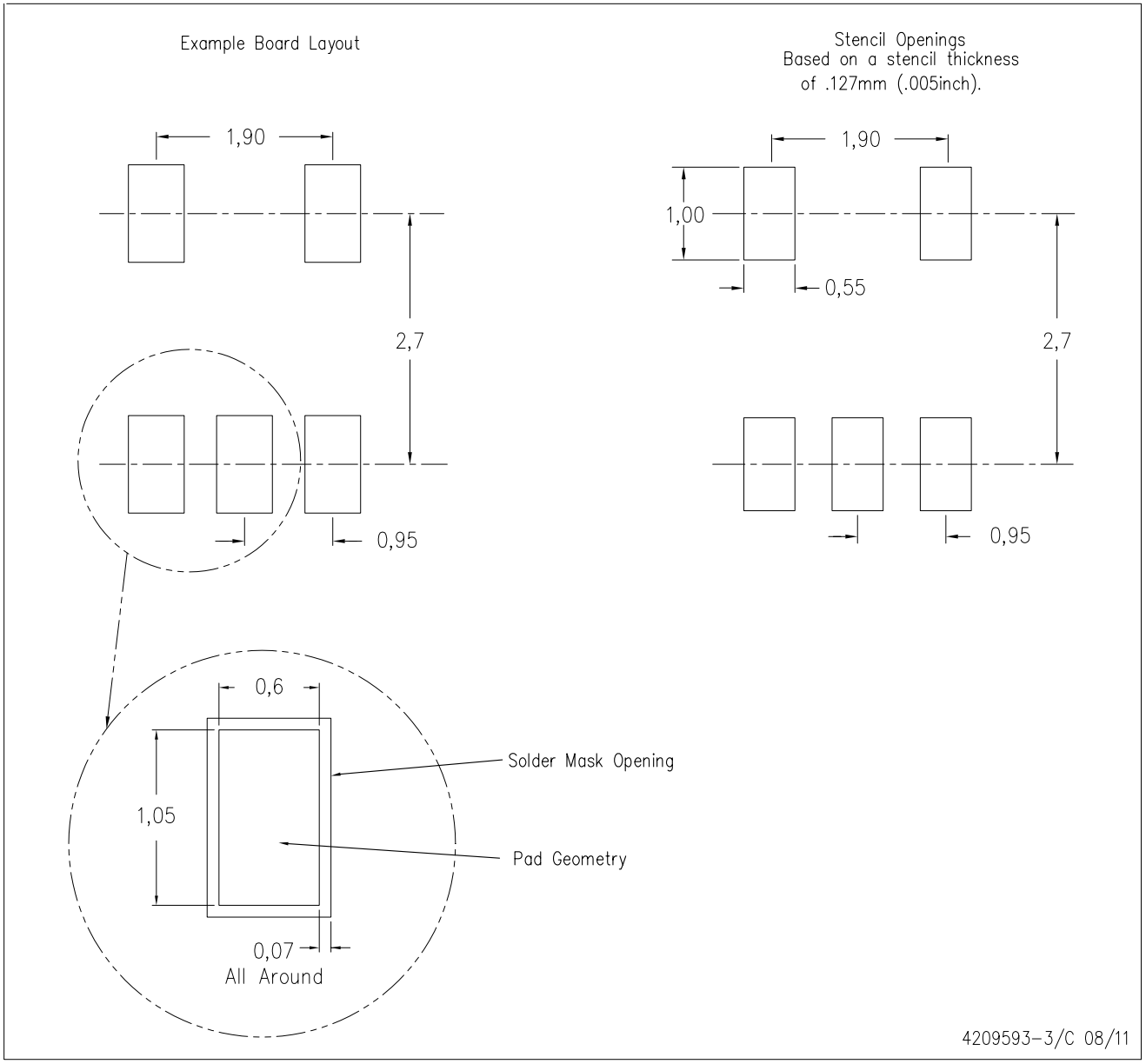
DBV (R–PDSO–G5) PLASTIC SMALL–OUTLINE PACKAGE



4073253–4/K 03/2006

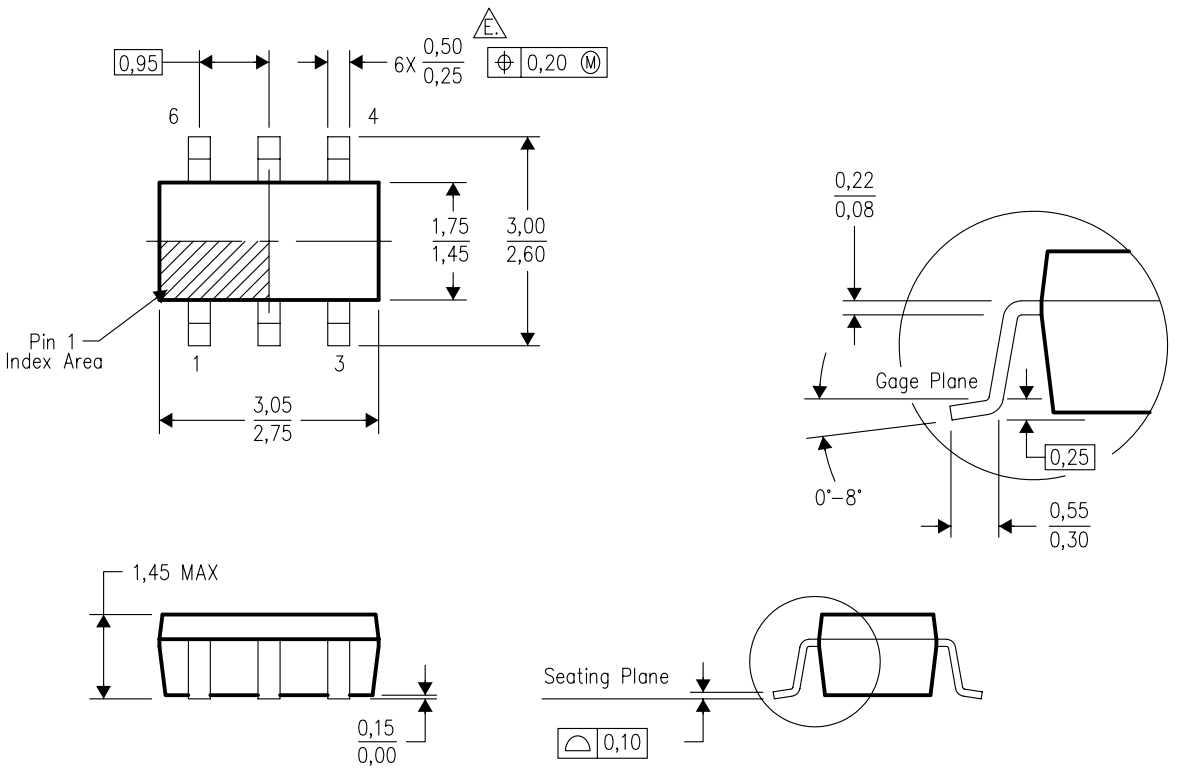
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO–178 Variation AA.

DBV (R–PDSO–G5) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.

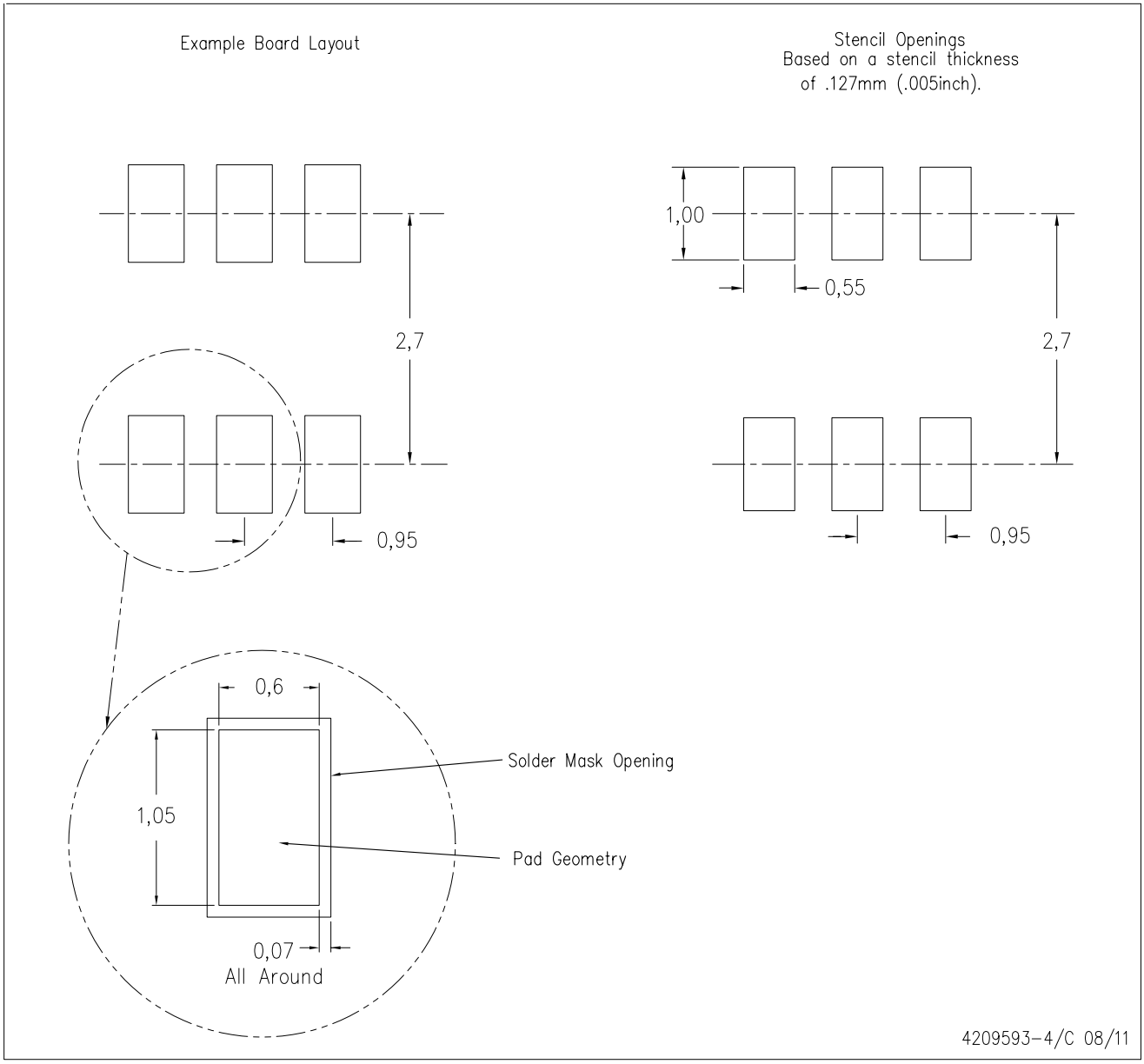
DBV (R–PDSO–G6) PLASTIC SMALL–OUTLINE PACKAGE



4073253–5/K 03/2006

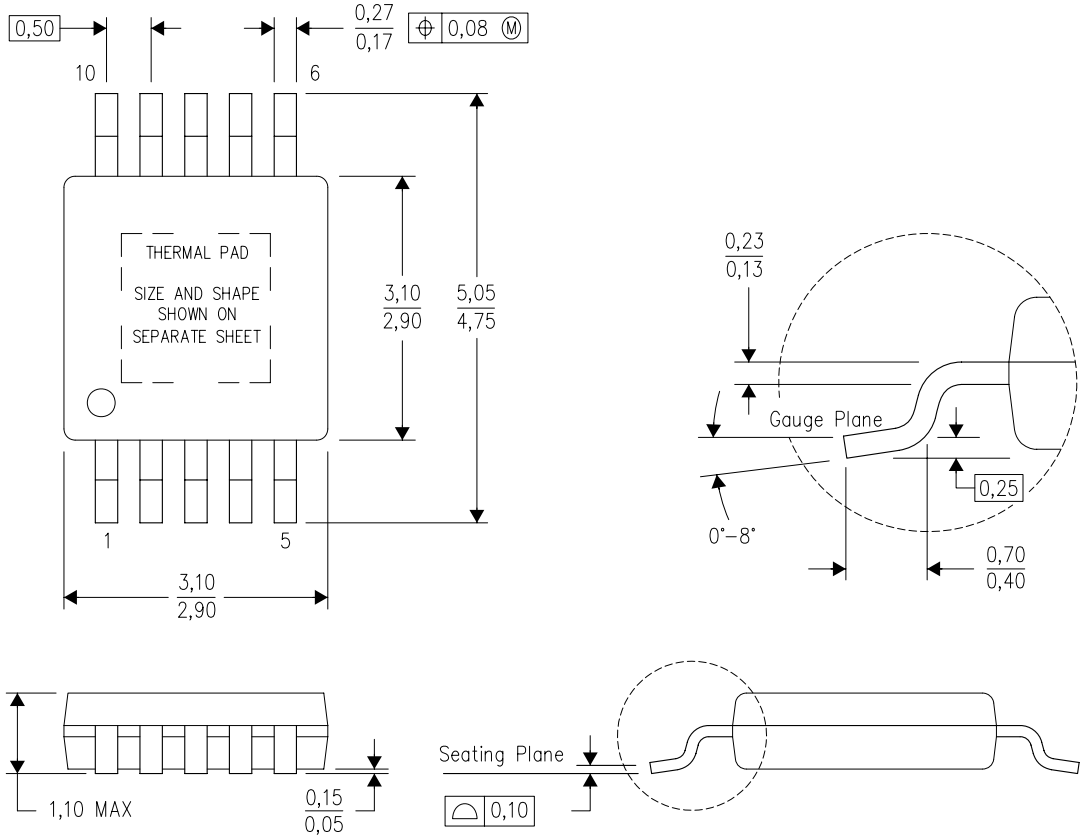
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
E. Falls within JEDEC MO–178 Variation AB, except minimum lead width.

DBV (R–PDSO–G6) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.

DGQ (S–PDSO–G10) PowerPAD™ PLASTIC SMALL OUTLINE



4073273/F 11/11

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Falls within JEDEC MO–187 variation BA–T.

PowerPAD is a trademark of Texas Instruments.

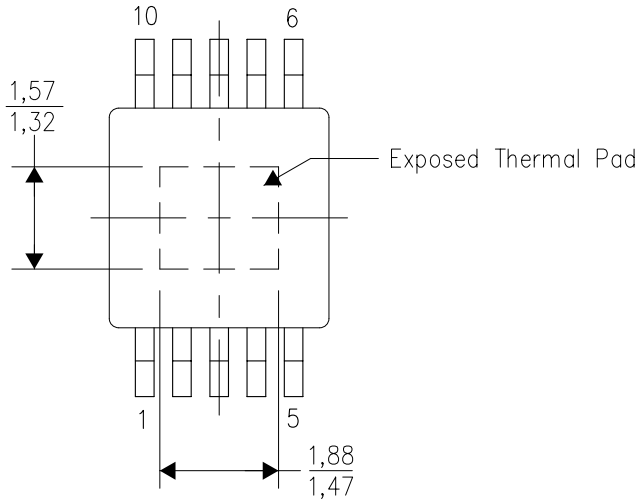
DGQ (S–PDSO–G10) PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

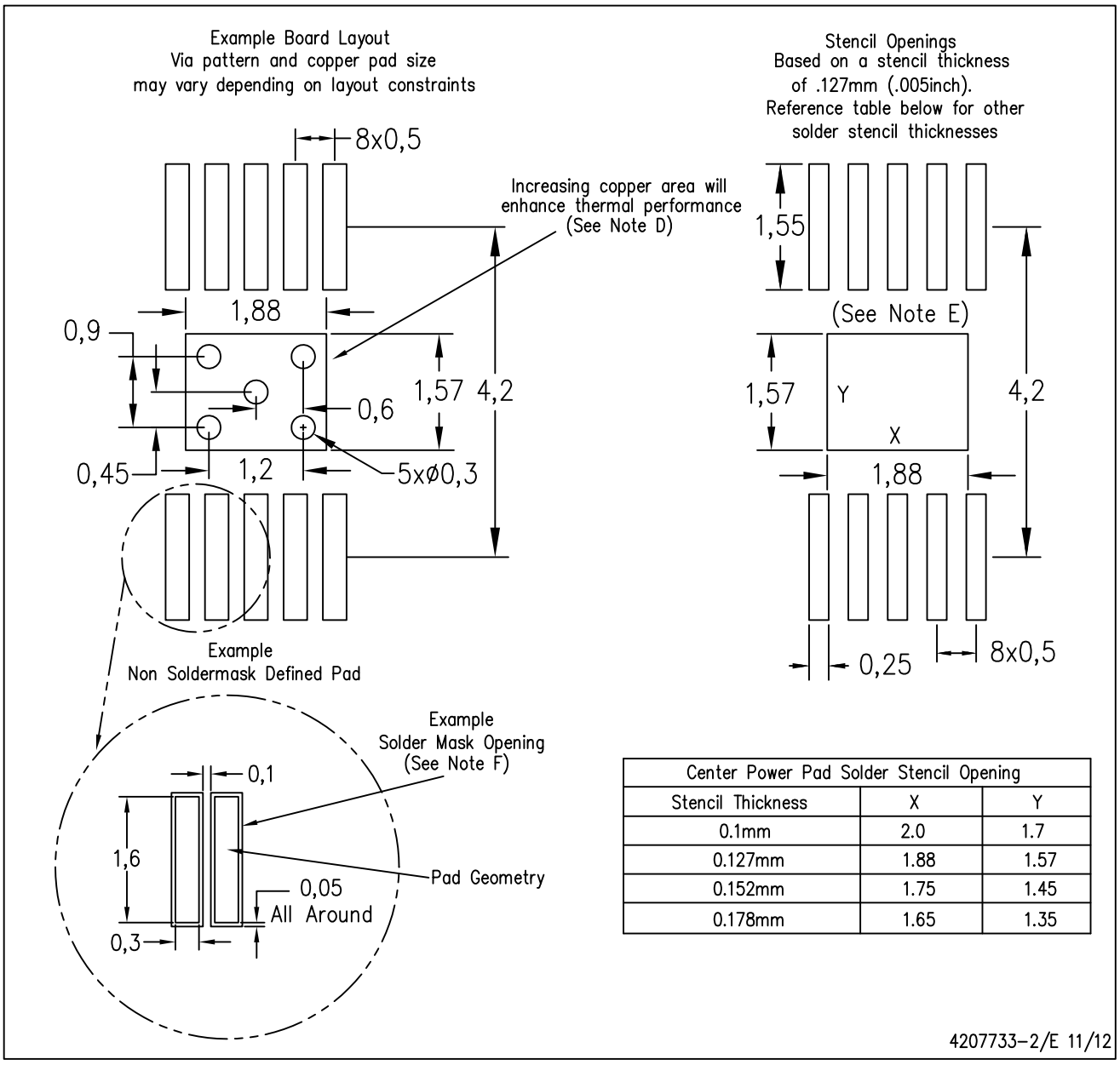
Exposed Thermal Pad Dimensions

4206324–2/F 01/11

NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

DGQ (S–PDSO–G10) PowerPAD™ PLASTIC SMALL OUTLINE



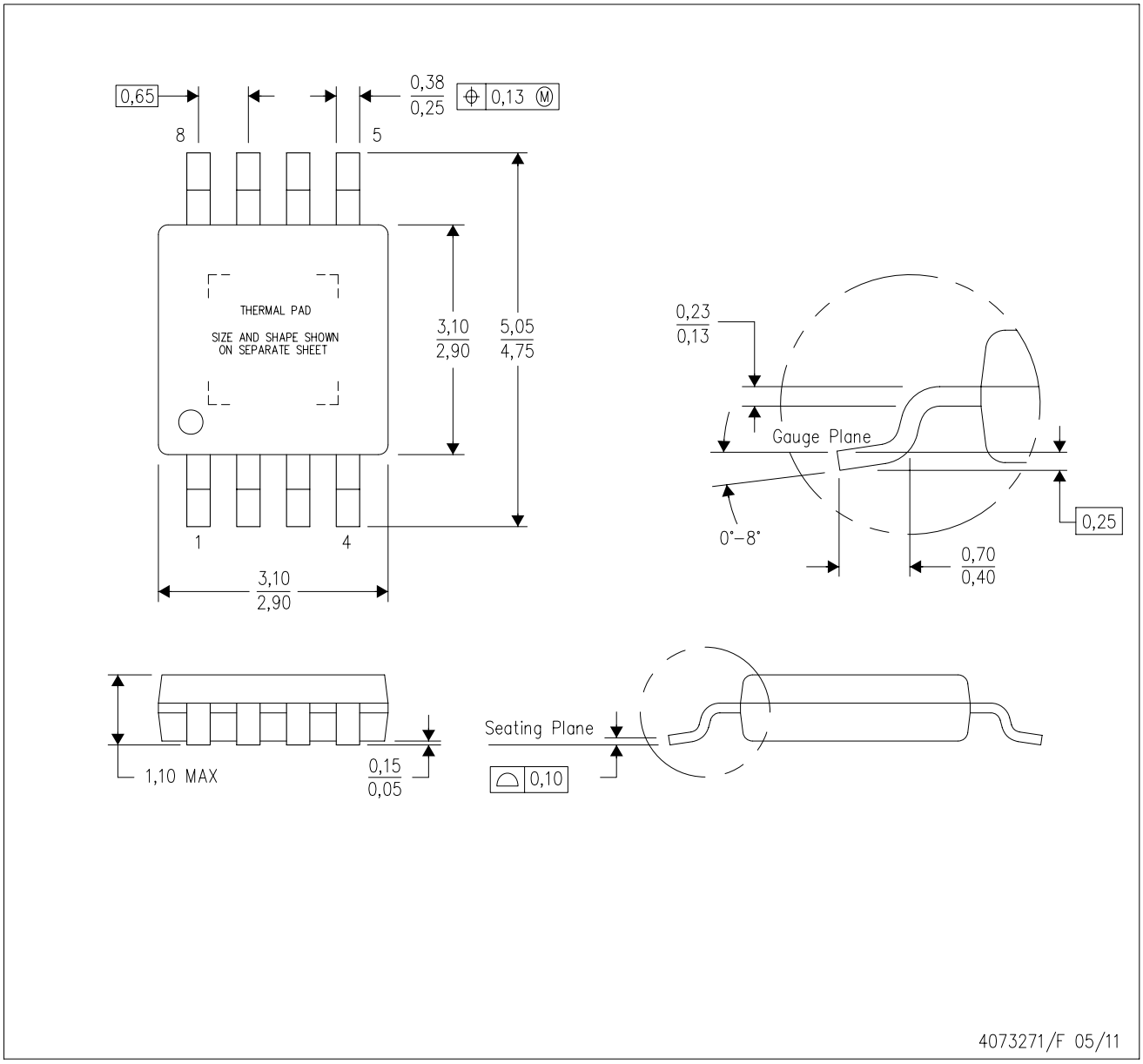
Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.0	1.7
0.127mm	1.88	1.57
0.152mm	1.75	1.45
0.178mm	1.65	1.35

4207733–2/E 11/12

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments

DGN (S–PDSO–G8) PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Falls within JEDEC MO–187 variation AA–T

PowerPAD is a trademark of Texas Instruments.

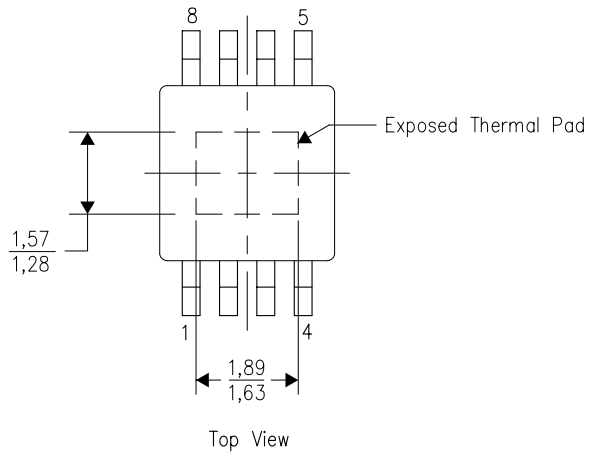
DGN (S–PDSO–G8) PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

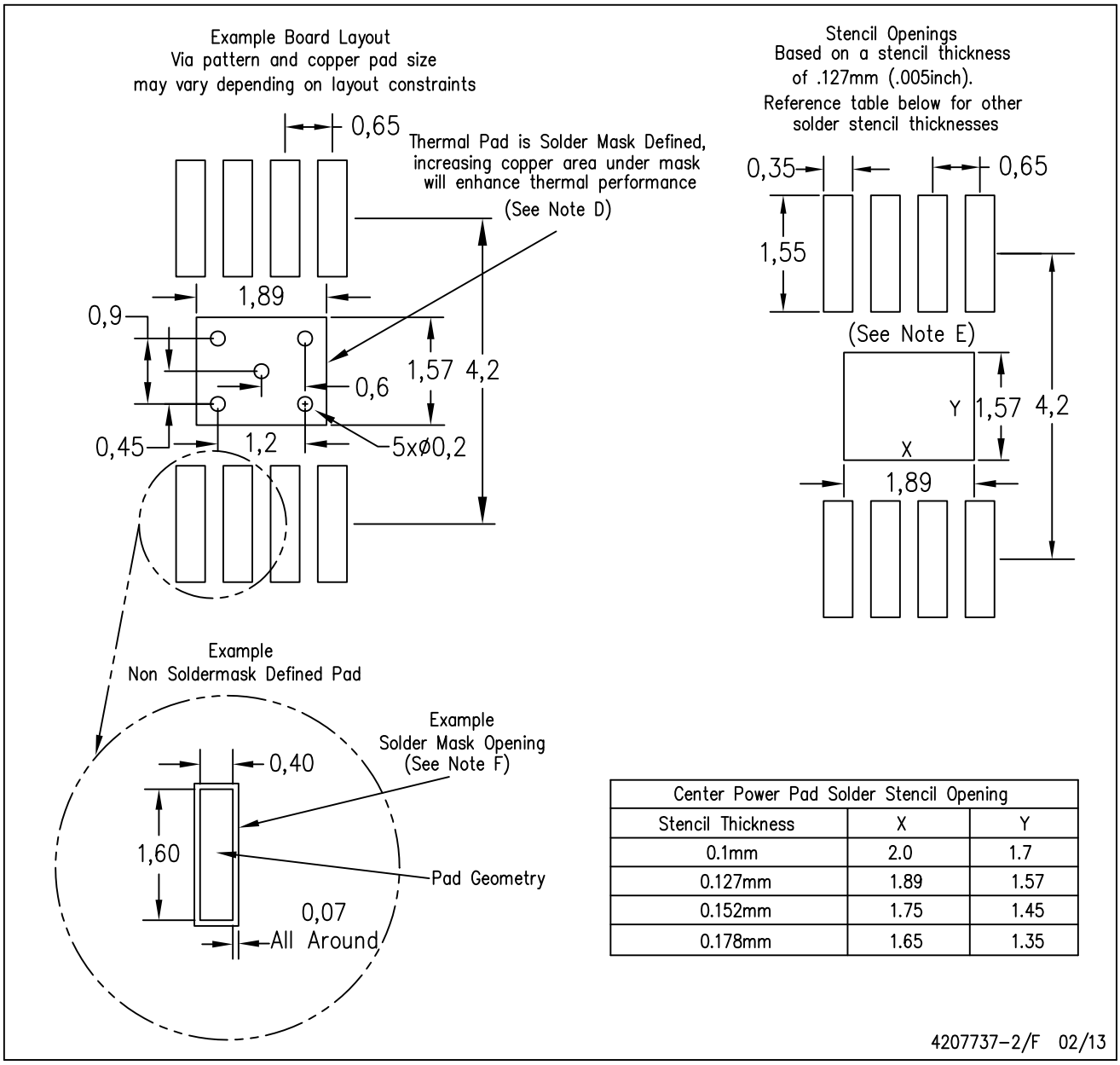
Exposed Thermal Pad Dimensions

4206323–2/I 12/11

NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

DGN (R–PDSO–G8) PowerPAD™ PLASTIC SMALL OUTLINE



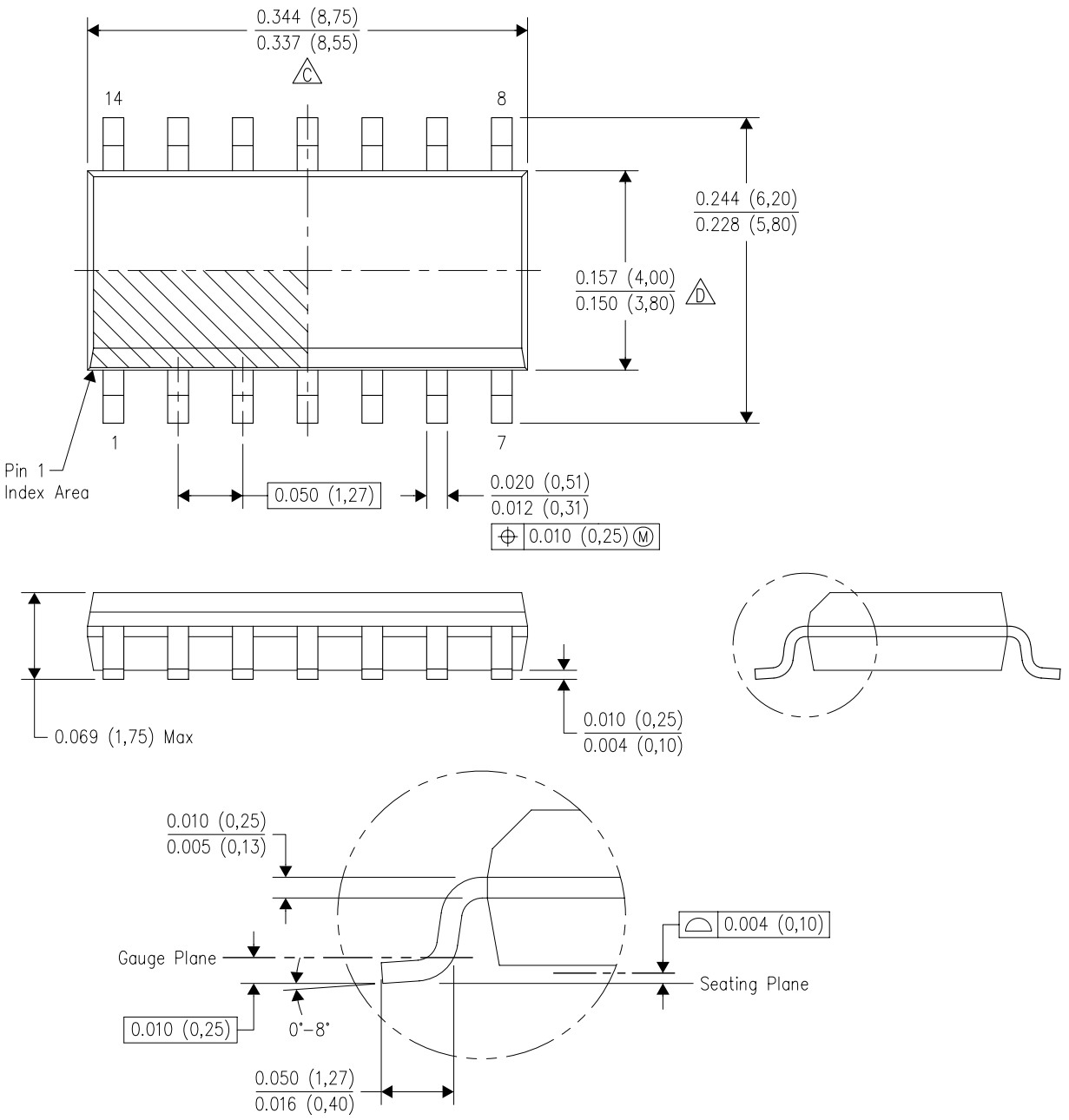
Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.0	1.7
0.127mm	1.89	1.57
0.152mm	1.75	1.45
0.178mm	1.65	1.35

4207737–2/F 02/13

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

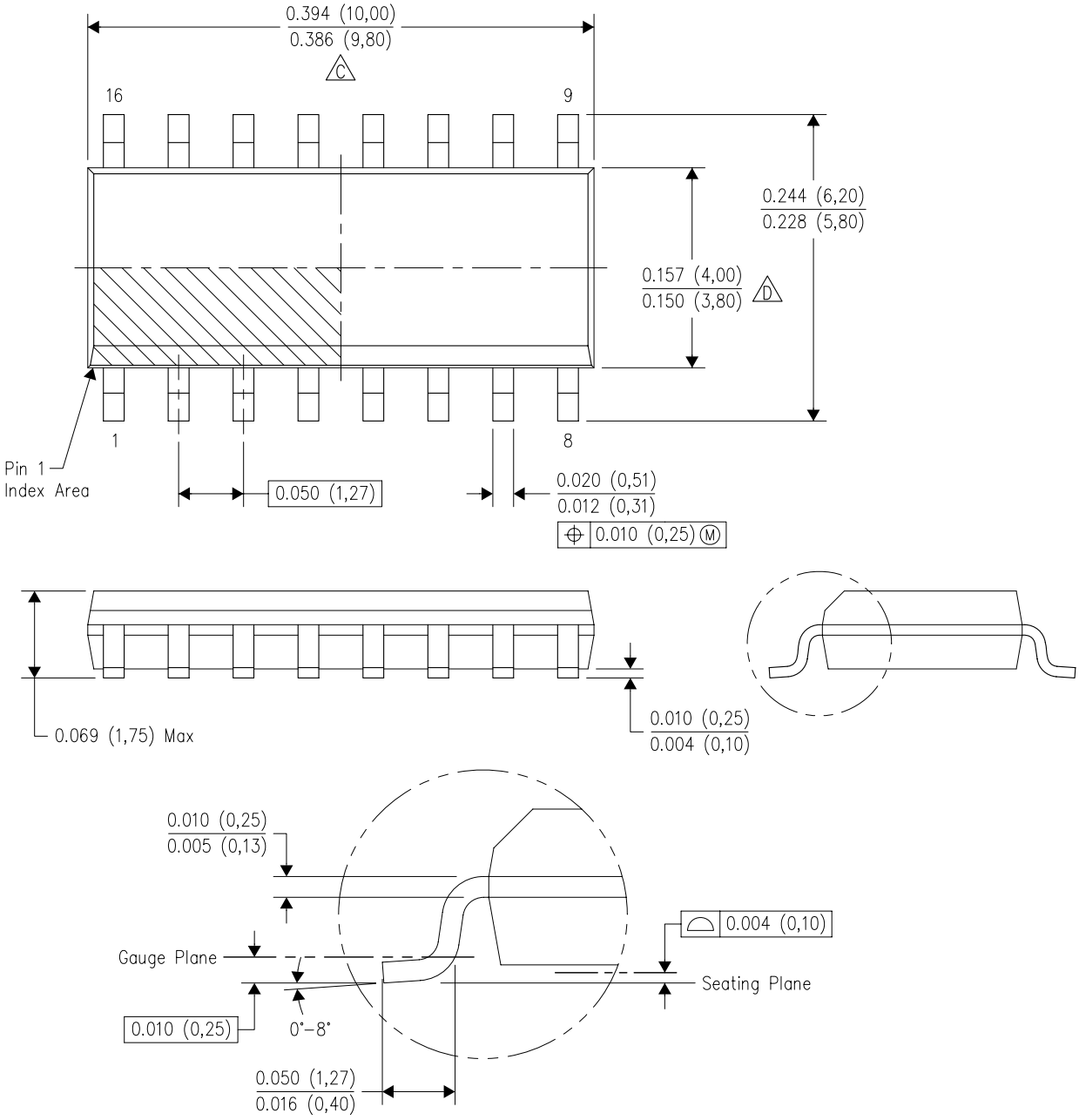
PowerPAD is a trademark of Texas Instruments

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



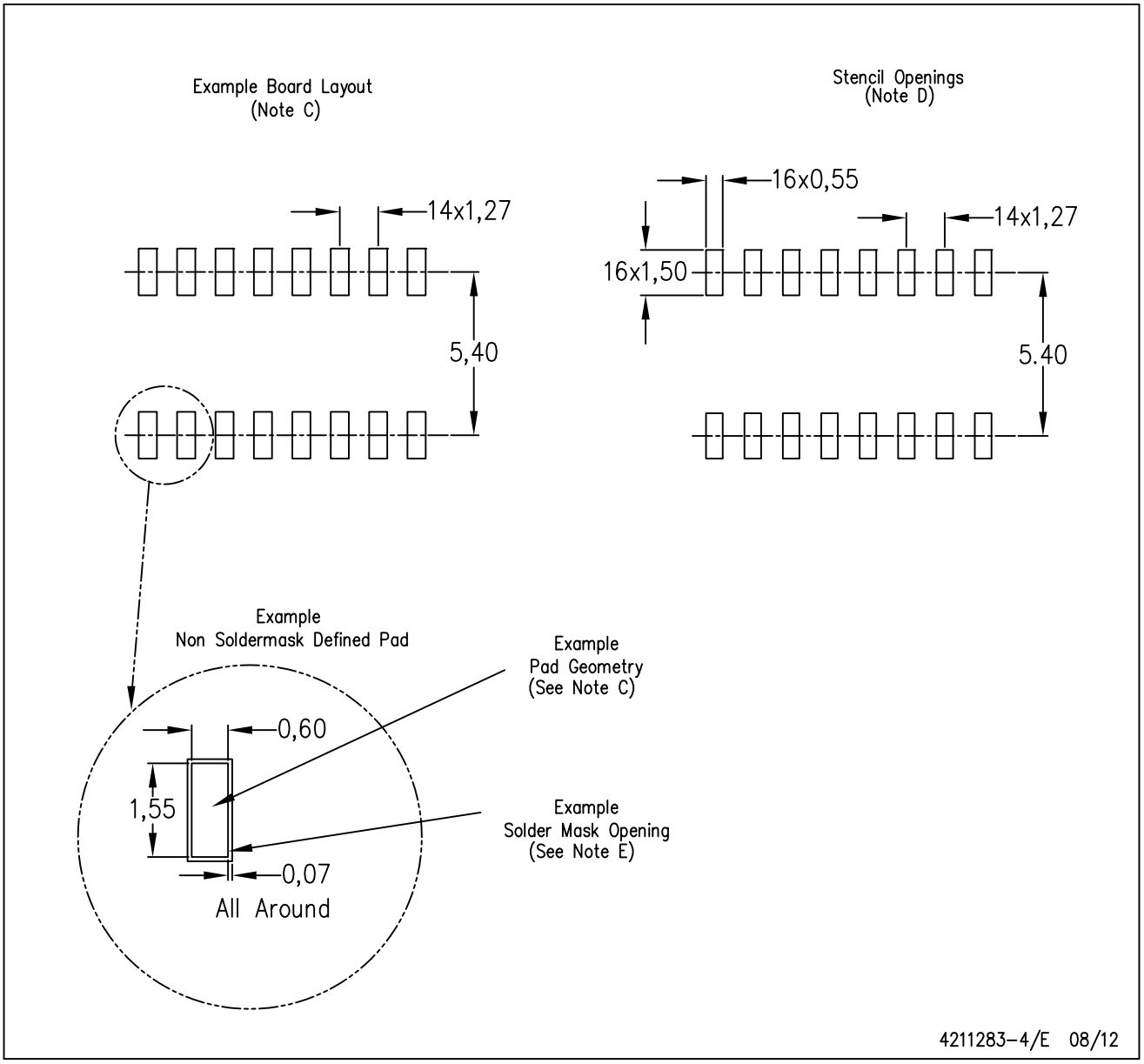
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



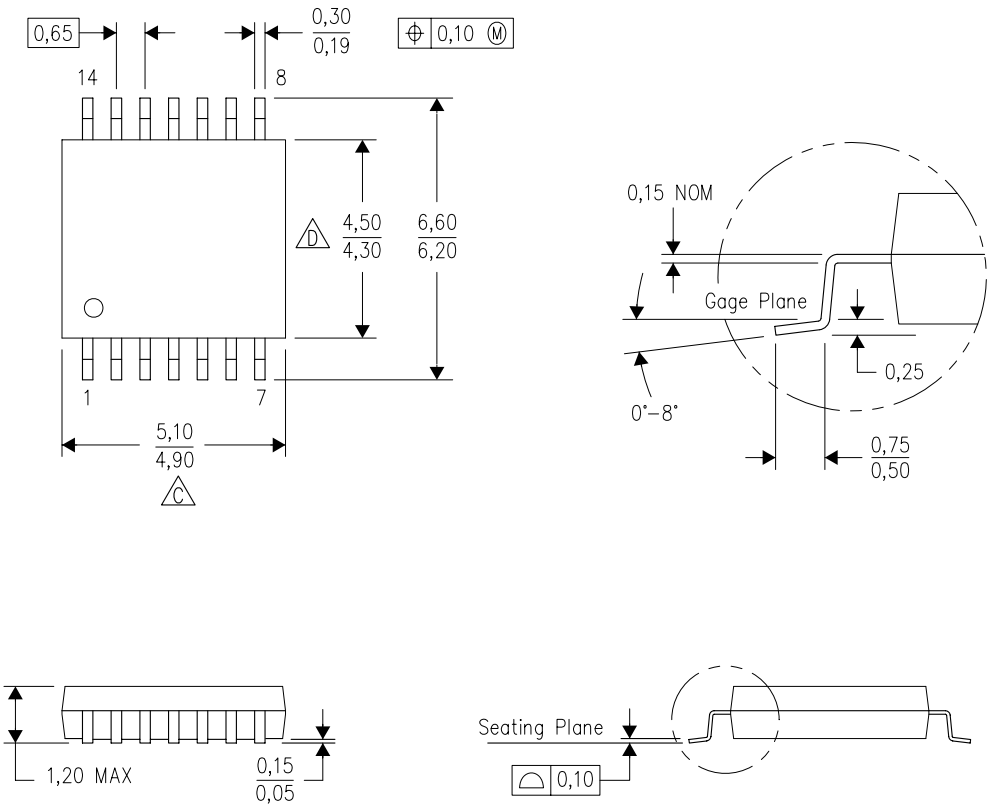
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

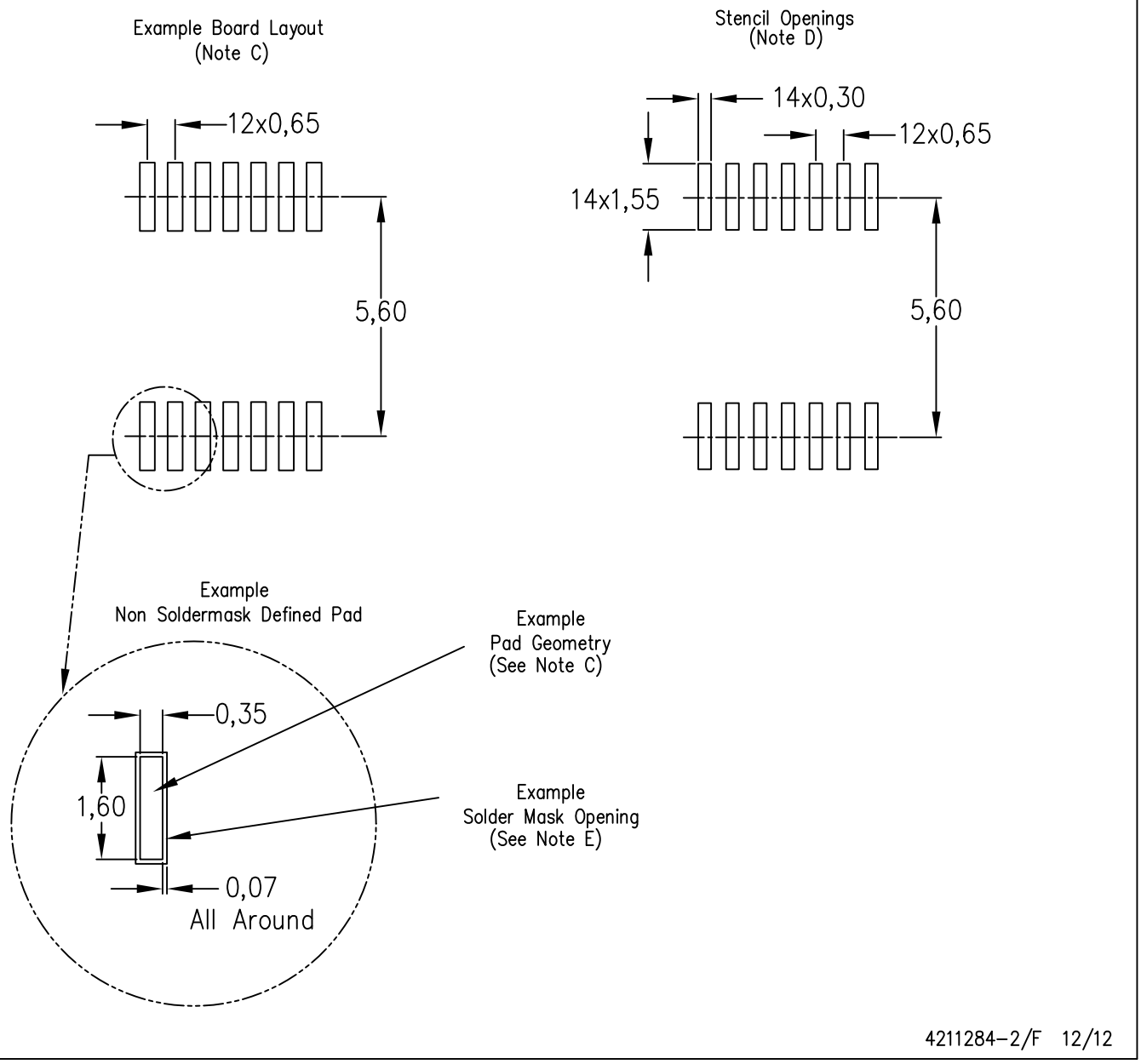
PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040064–3/G 02/11

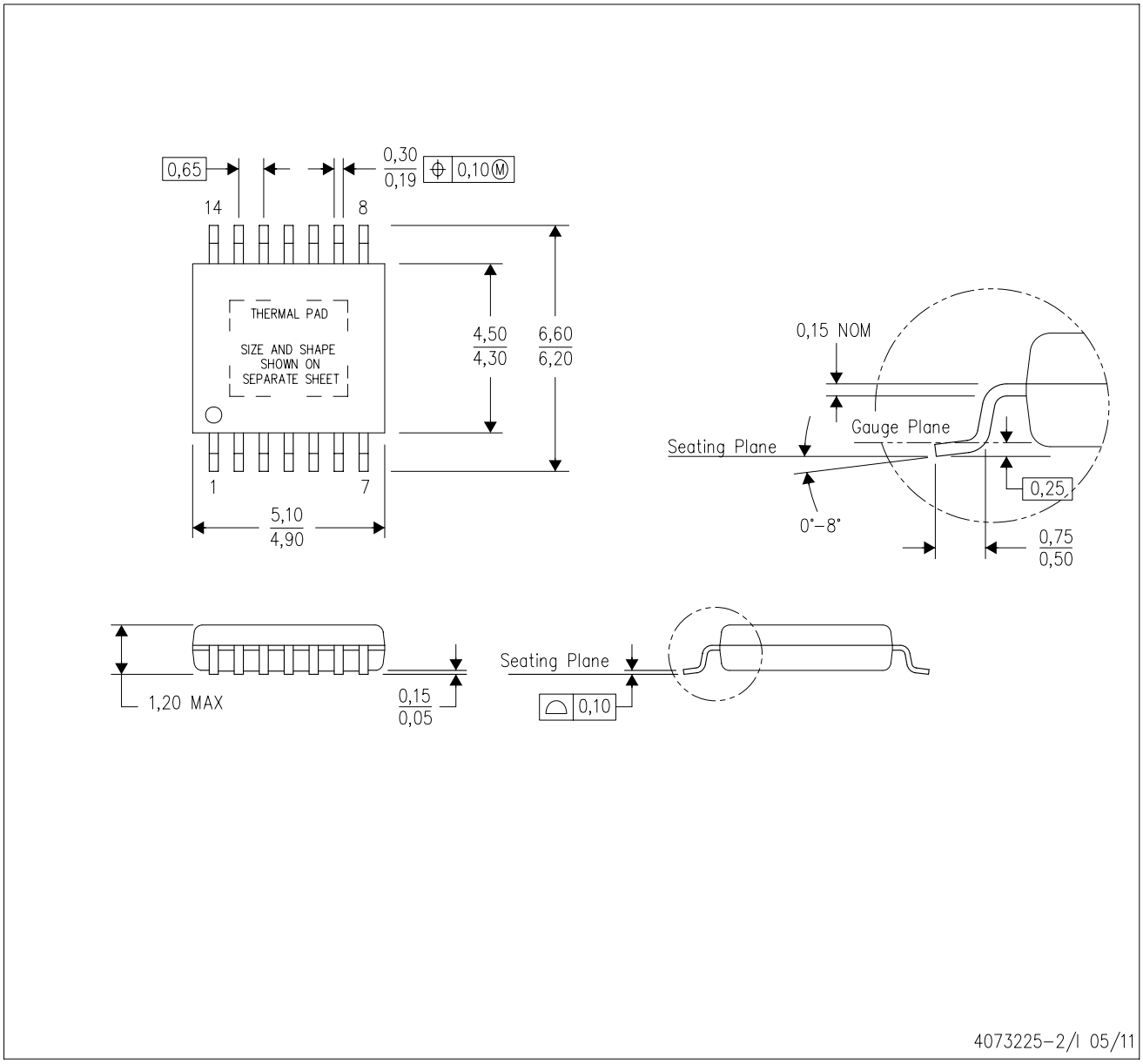
NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PWP (R–PDSO–G14) PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
E. Falls within JEDEC MO–153

PowerPAD is a trademark of Texas Instruments.

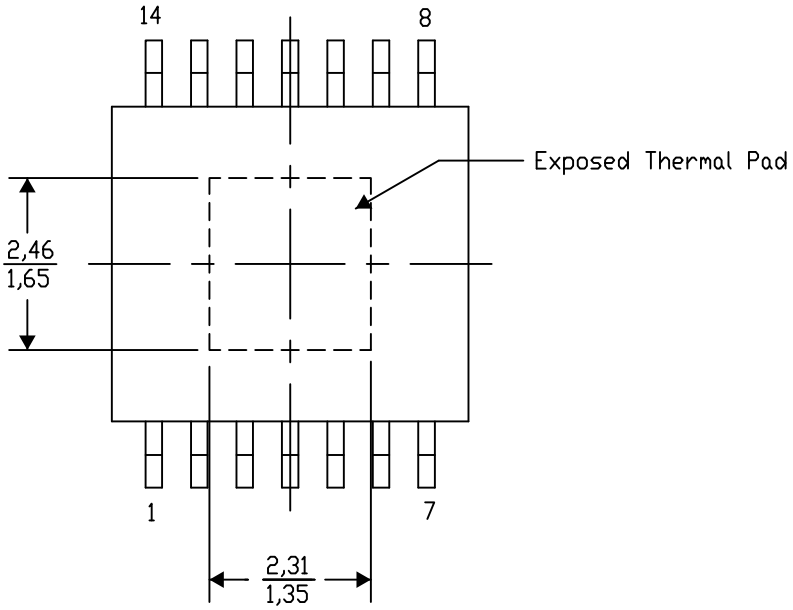
PWP (R–PDSO–G14) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332–2/AD 01/13

NOTE: A. All linear dimensions are in millimeters

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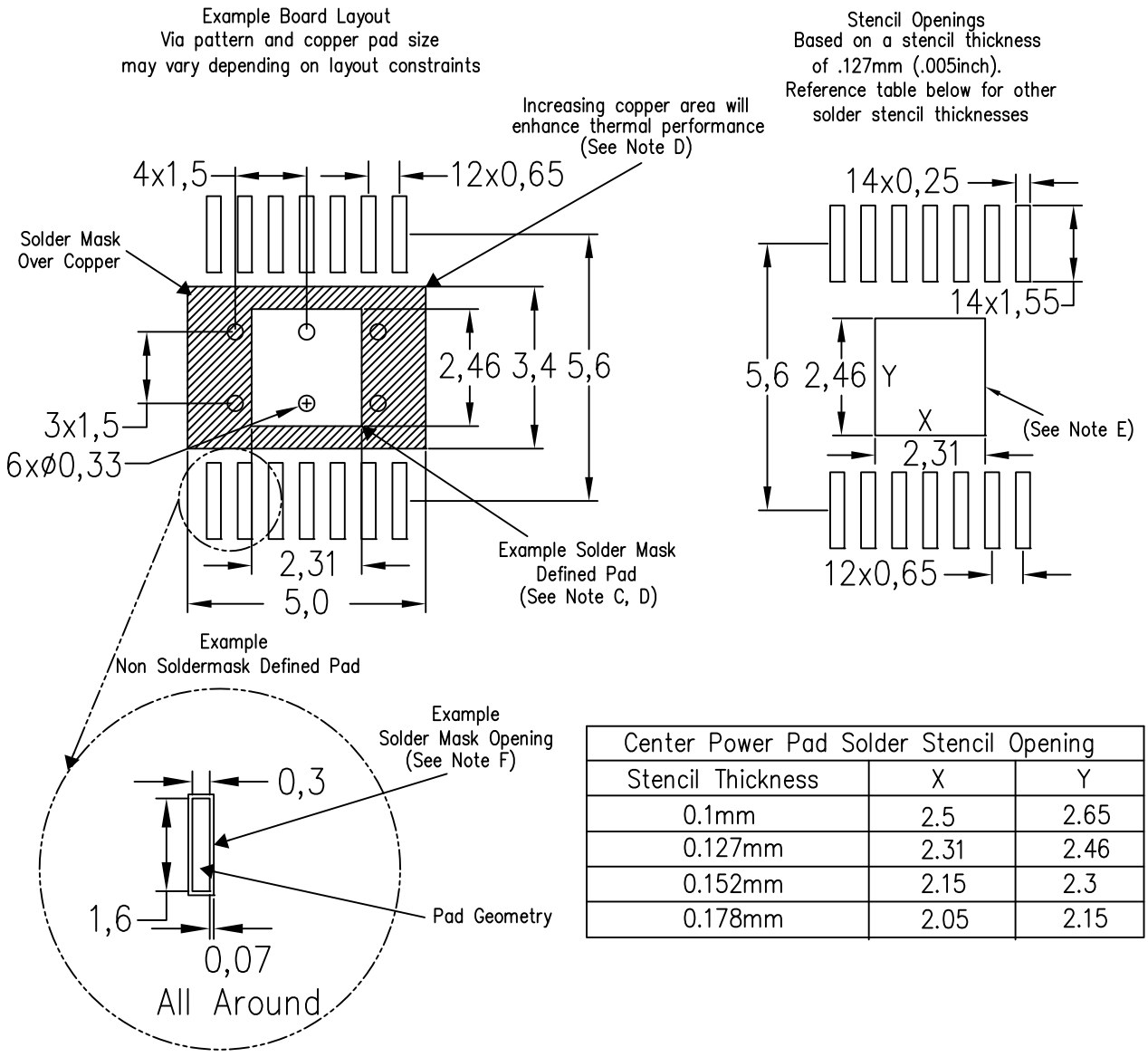
PWP (R–PDSO–G14) PowerPAD™ PLASTIC SMALL OUTLINE



Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.5	2.65
0.127mm	2.31	2.46
0.152mm	2.15	2.3
0.178mm	2.05	2.15

4207609–2/S 02/13

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

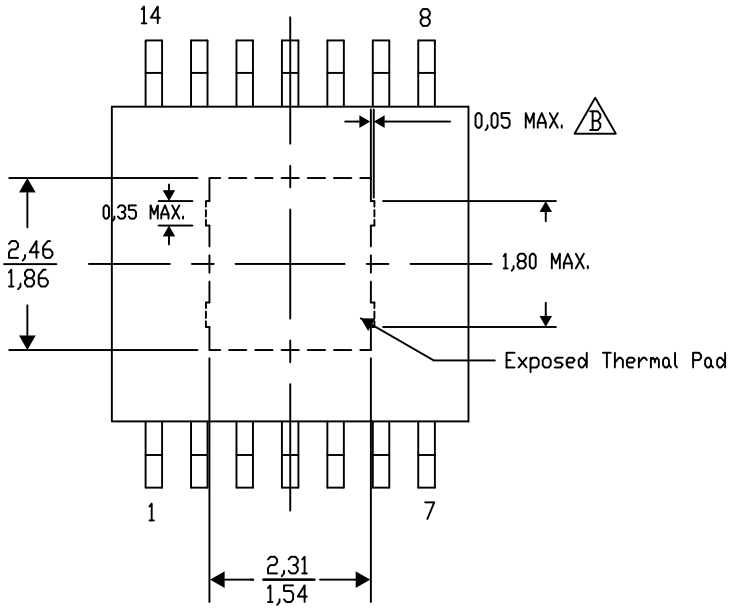
PWP (R–PDSO–G14) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

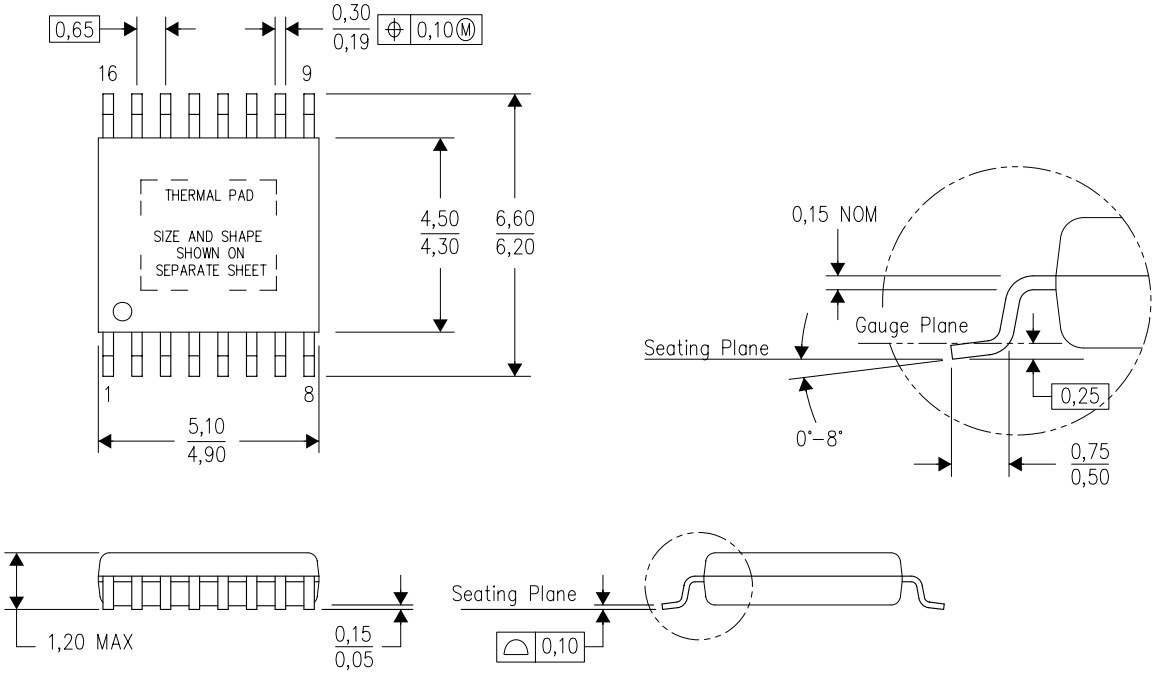
4206332–44/AD 01/13

NOTE: A. All linear dimensions are in millimeters

B. Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments

PWP (R–PDSO–G16) PowerPAD™ PLASTIC SMALL OUTLINE



4073225–3/I 05/11

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
E. Falls within JEDEC MO–153

PowerPAD is a trademark of Texas Instruments.

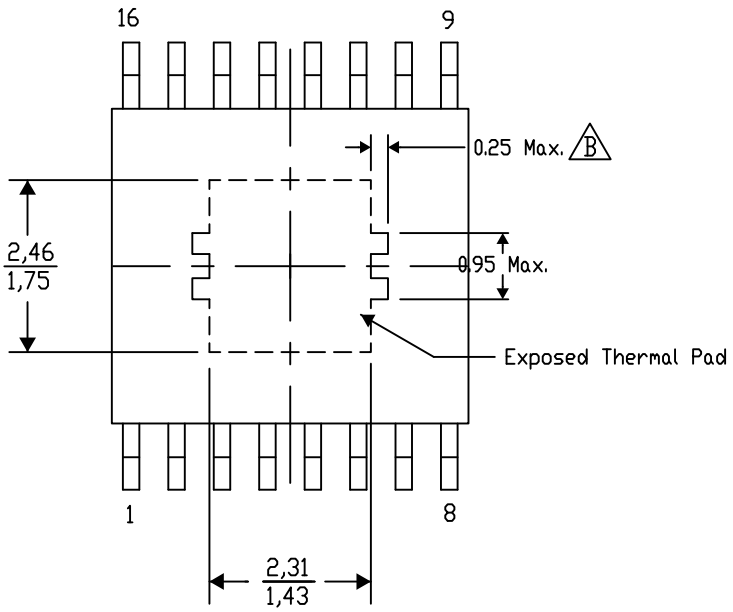
PWP (R–PDSO–G16) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

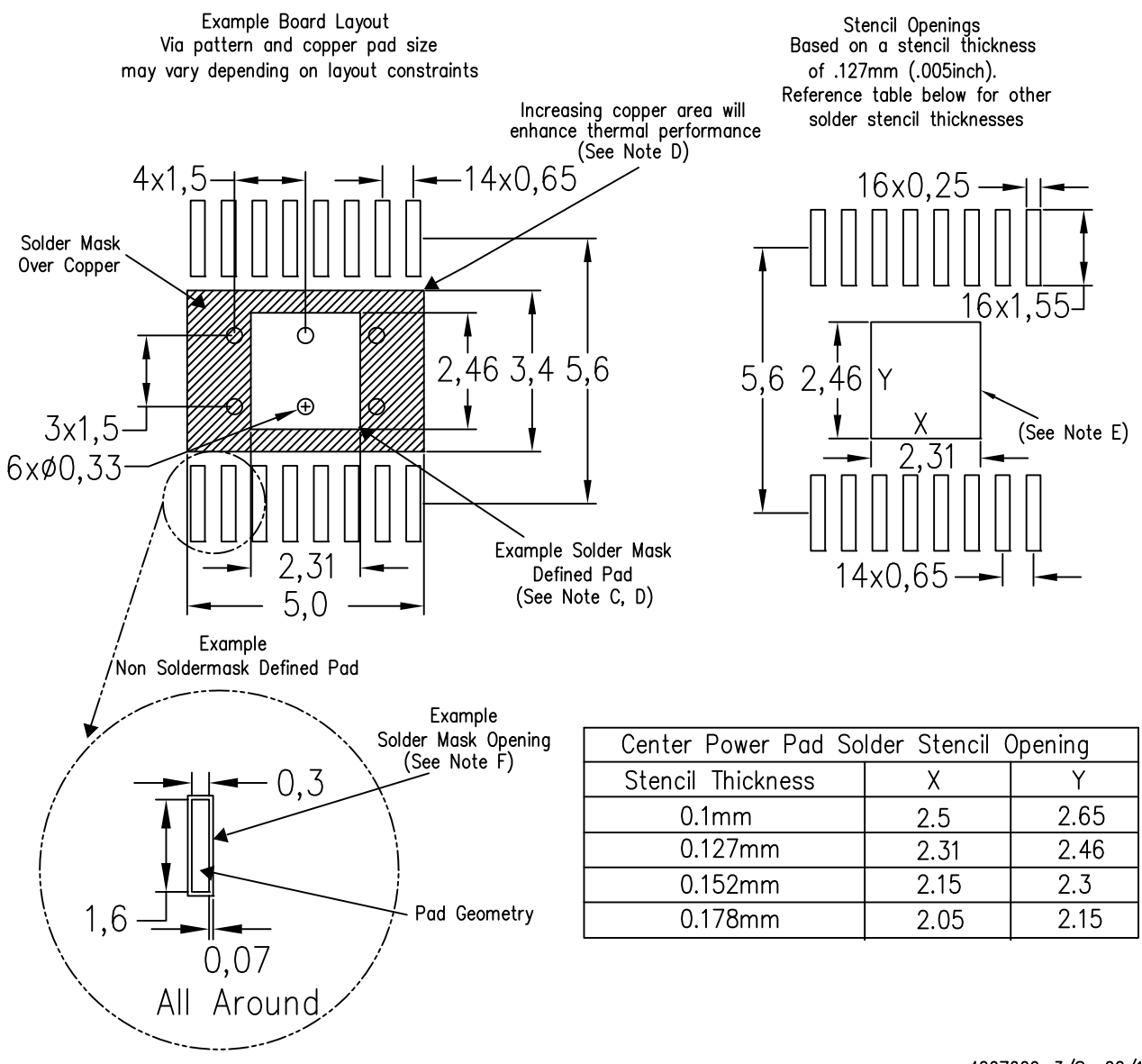
4206332–6/AD 01/13

NOTE: A. All linear dimensions are in millimeters

B. Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments

PWP (R–PDSO–G16) PowerPAD™ PLASTIC SMALL OUTLINE

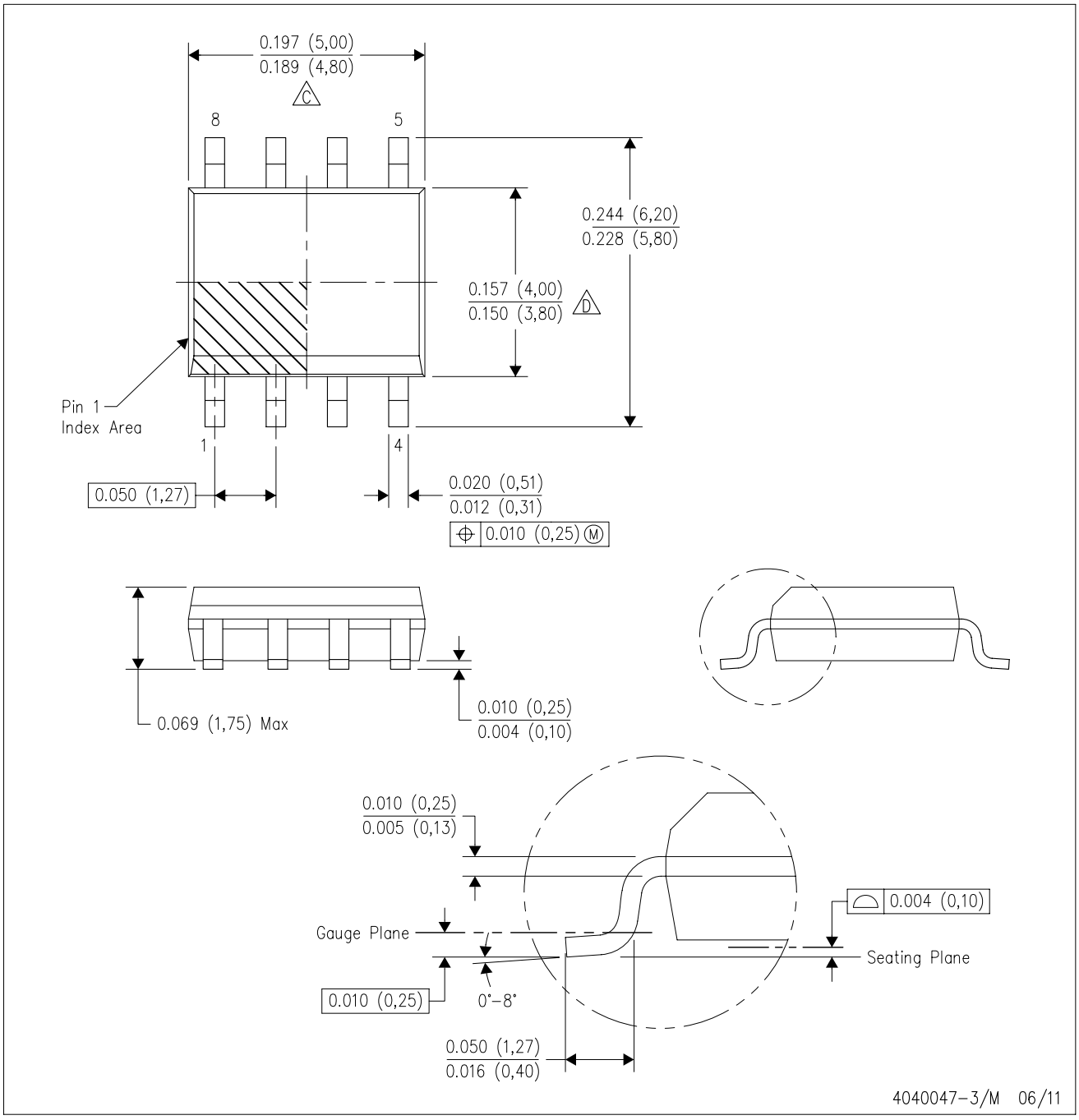


Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	2.5	2.65
0.127mm	2.31	2.46
0.152mm	2.15	2.3
0.178mm	2.05	2.15

4207609–3/S 02/13

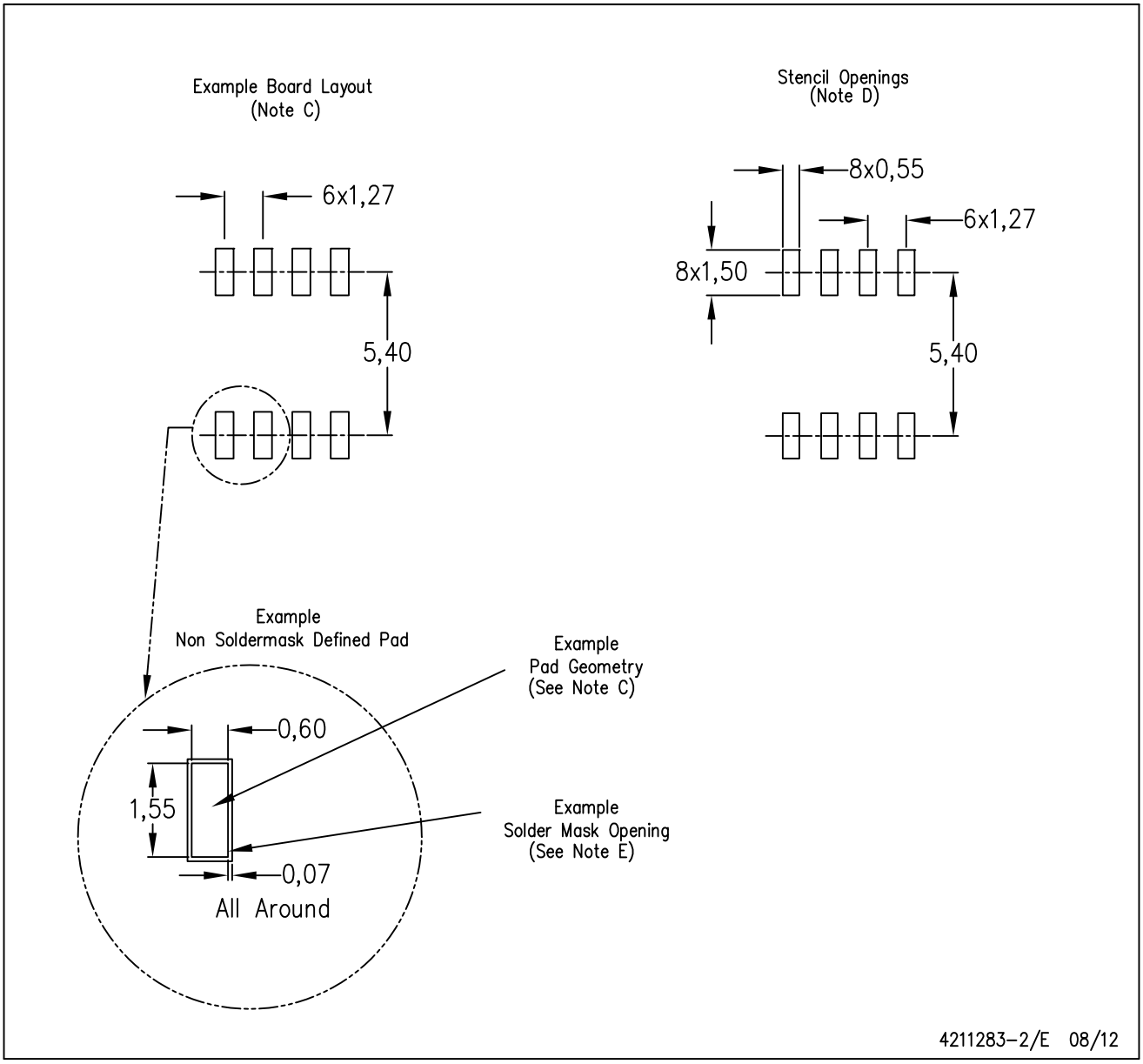
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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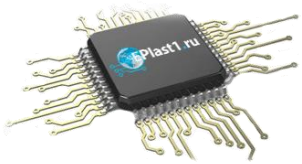

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